

Power Supply for accelerator

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Chinese Academy of Science

中国科学院高能物理研究所



Content

- **Power components;**
- **Power supply classification;**
- **Power supply parameters definitions;**
- **Regulation Loop;**
- **CSNS PS system;**



Power electronics needs the knowledge of :

- Power electronic devices;
- Regulation theory;
- High precision measurement;
- Analog circuit technology;
- Digital circuit technology;
- Mechanical capabilities;
- Cooling technology;
- Control system;
- Databases;
- Programming, internet, FPGAs, DPSs, PLCs.....;
- Simulation tools.



Content

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- **Power supply classification;**
- **Power supply parameters definitions;**
- **Regulation Loop;**
- **CSNS PS system;**



Energy source



Applications

Power supply (Power converter)

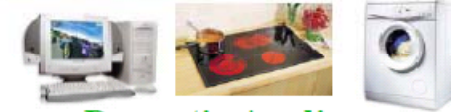
The task for a PS is to process and control the flow of electric energy by voltages and currents in a form that is optimally suited for user loads



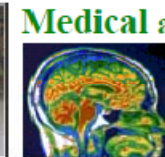
control



Traction
and auxiliary



Domestic Appliance

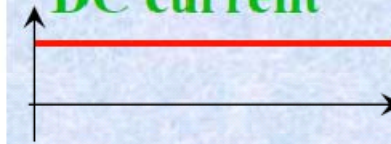


Medical applications

Industrial applications, Welding,
Induction Heating,

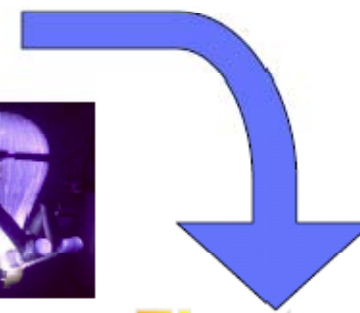
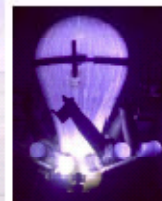


DC current



Evolution of Power semiconductors

From mercury arc rectifier,
grid-controlled vacuum-tube
rectifier, ignitron ,....



Power Electronics

From 1960

Power Diode and Thyristor

or SCR (Silicon-Controlled Rectifier)



Link to frequency of the
electrical network
50 Hz (60 Hz)

From 1985

High frequency power semiconductors :

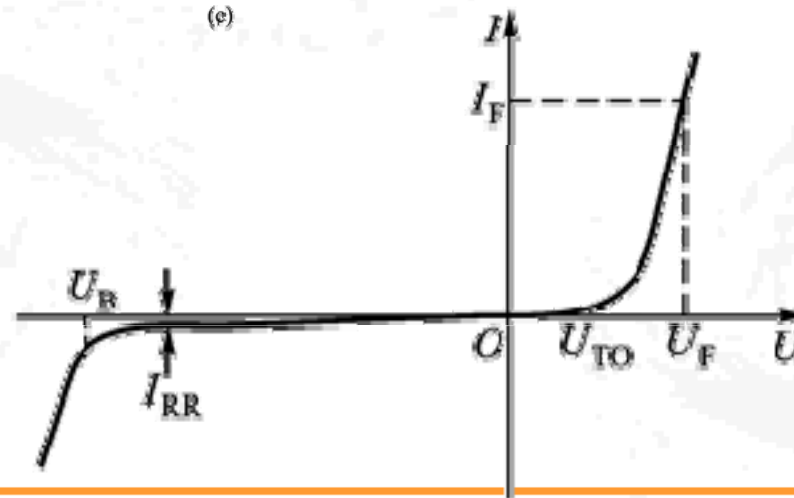
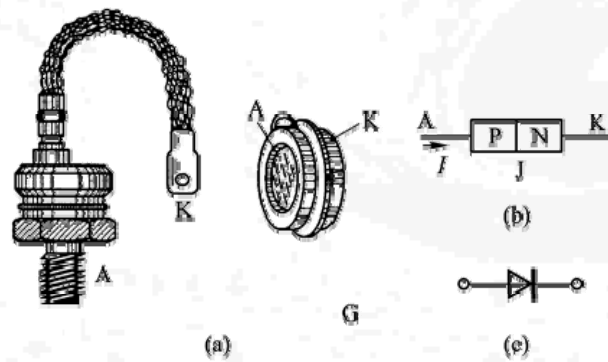
MosFet, IGBTs , GTOs, MCTs,....



High frequency => high
performances (ripple,
bandwidth, perturbation
rejection,...)
small magnetic
(volume, weight)



Power Diode

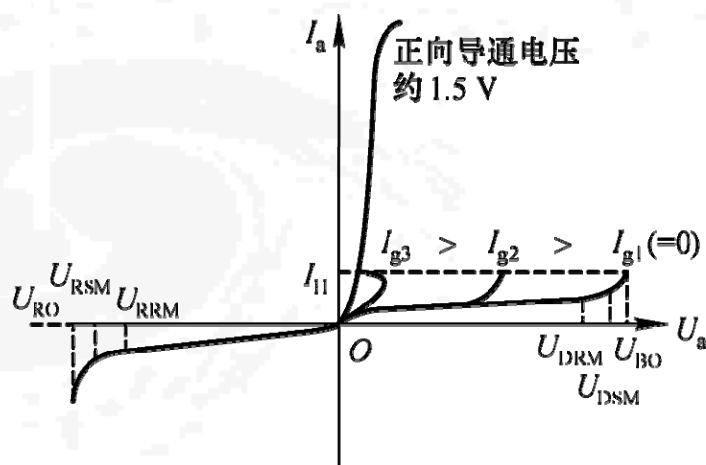
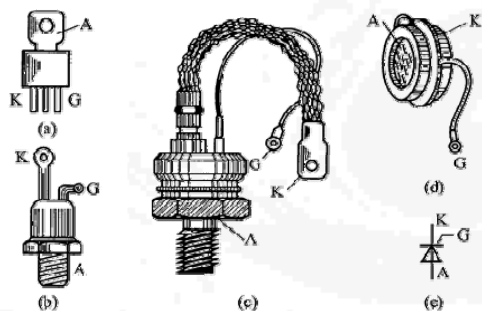


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Thyristor

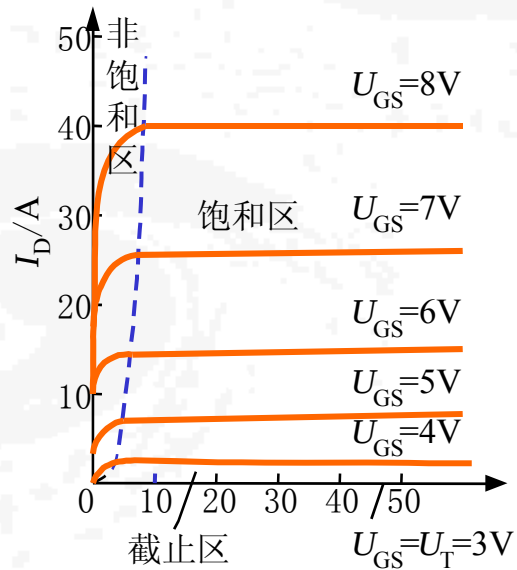
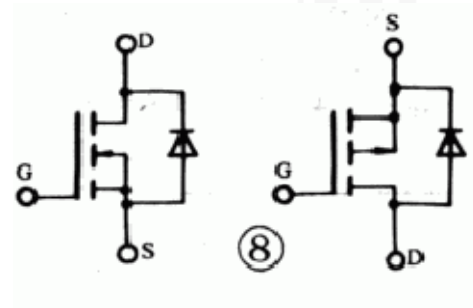


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MOSFET (MetalOxide Semiconductor Field Effect Transistor)

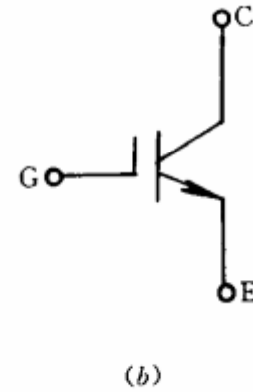
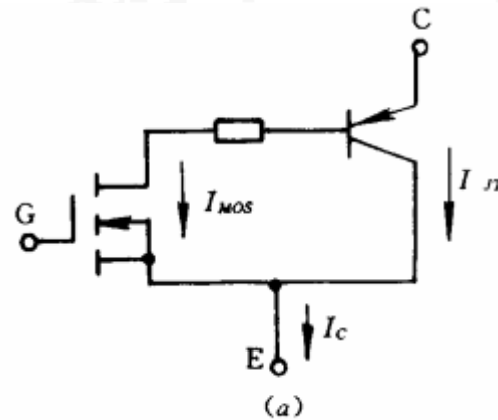


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IGBT (Insulated Gate Bipolar Transistor)



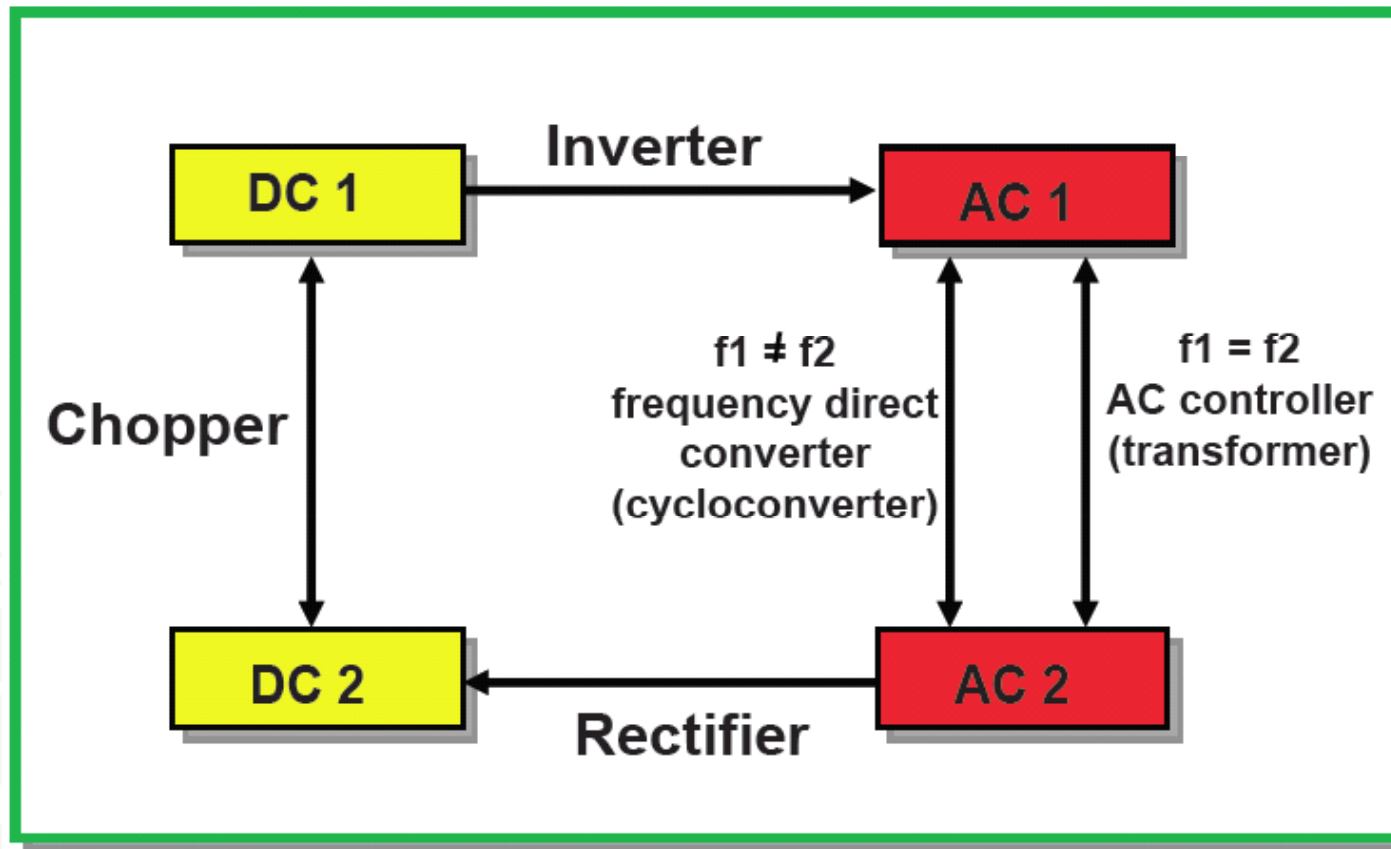
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- Power components;
- **Power supply classification;**
- Power supply parameters definitions;
- Regulation Loop;
- CSNS PS system;

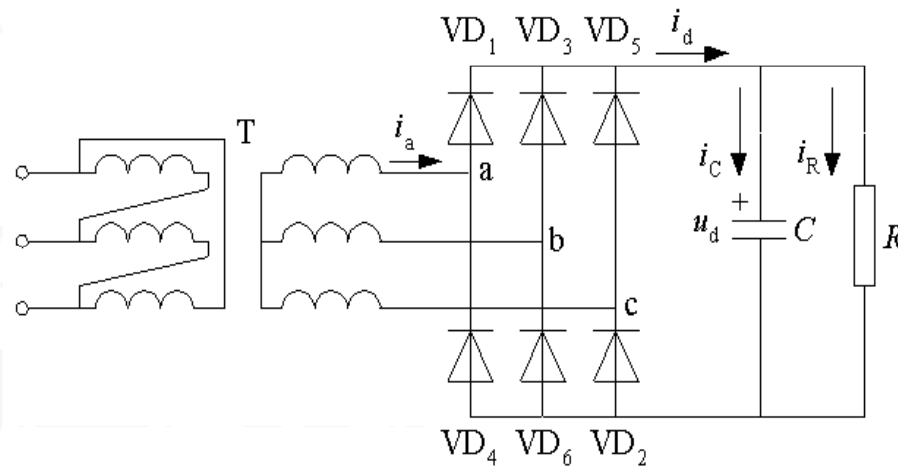




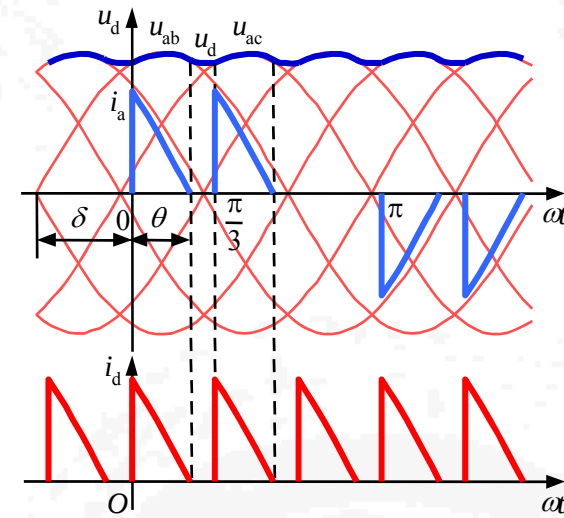
Power Supply classification



Diode Rectifier

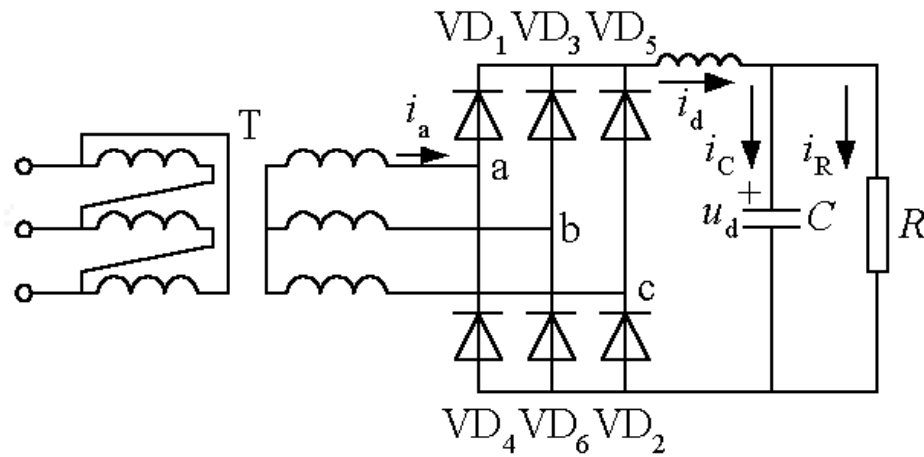


a)

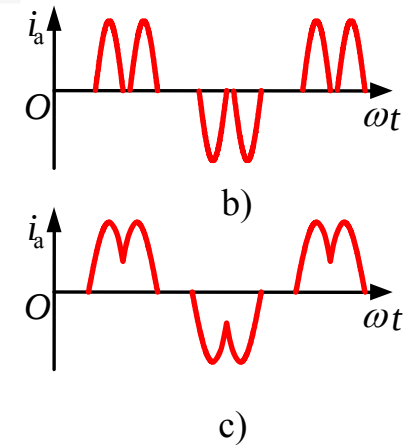


b)





a)



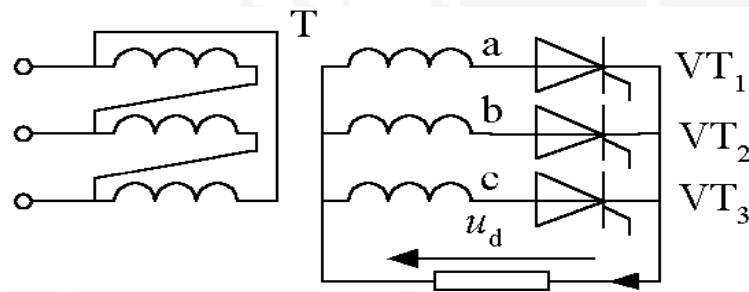
$$U_d = (2.34 \sim 2.45U)$$

$$I_R = U_d / R$$

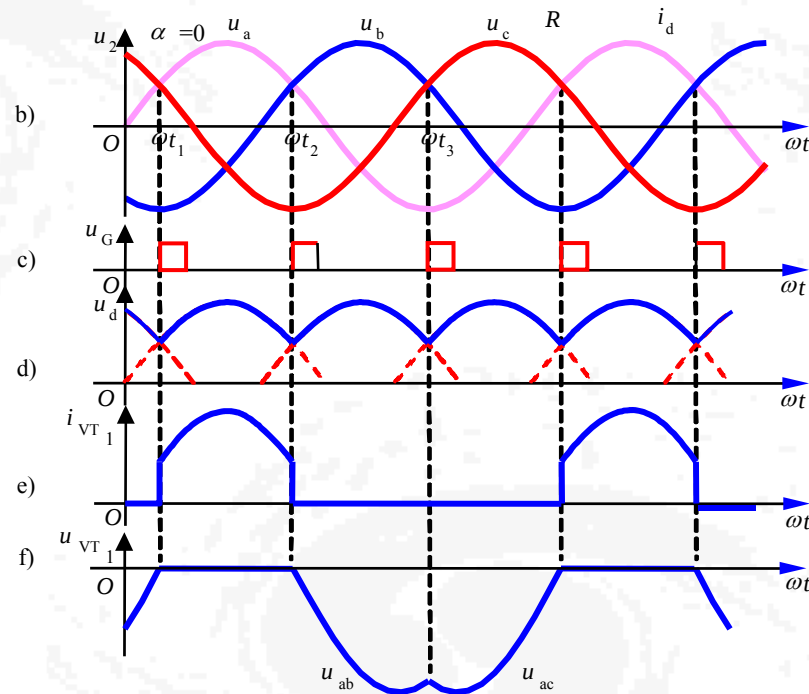
$$I_D = I_d / 3 = I_R / 3$$

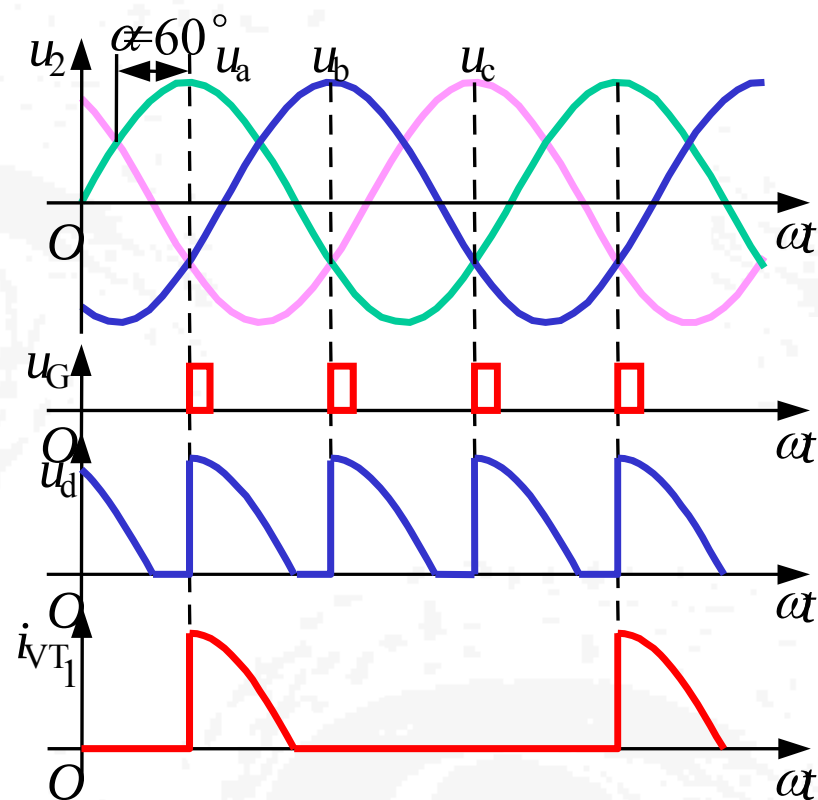
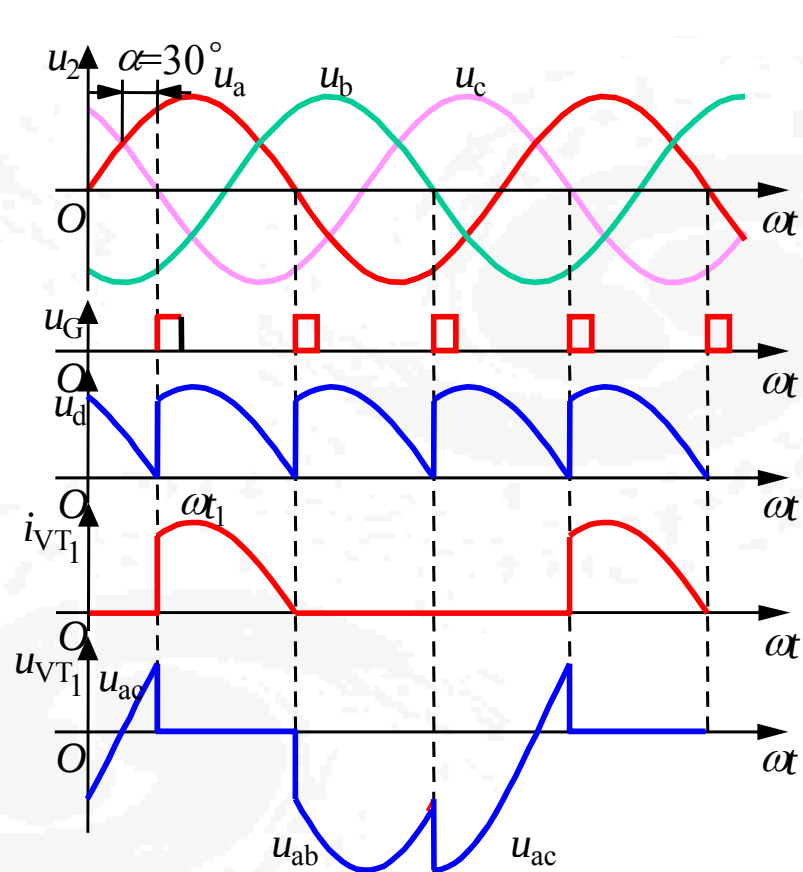


SCR (Silicon Controlled Rectifier)



Half wave SCR





$$\alpha \leq 30^\circ$$

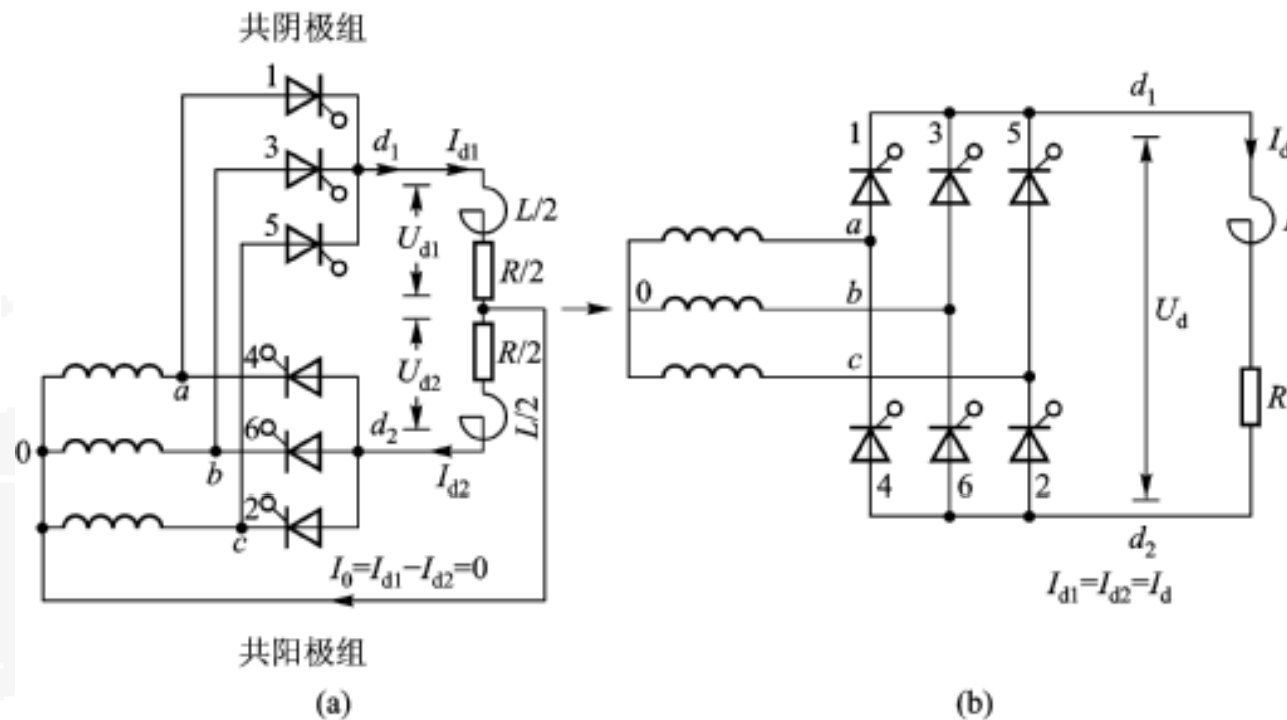
$$U_d = \frac{1}{\frac{2\pi}{3}} \int_{\frac{\pi}{6} + \alpha}^{\frac{5\pi}{6} + \alpha} \sqrt{2} U_2 \sin \omega t d(\omega t) = \frac{3\sqrt{6}}{2\pi} U_2 \cos \alpha = 1.17 U_2 \cos \alpha$$

$$\alpha > 30^\circ$$

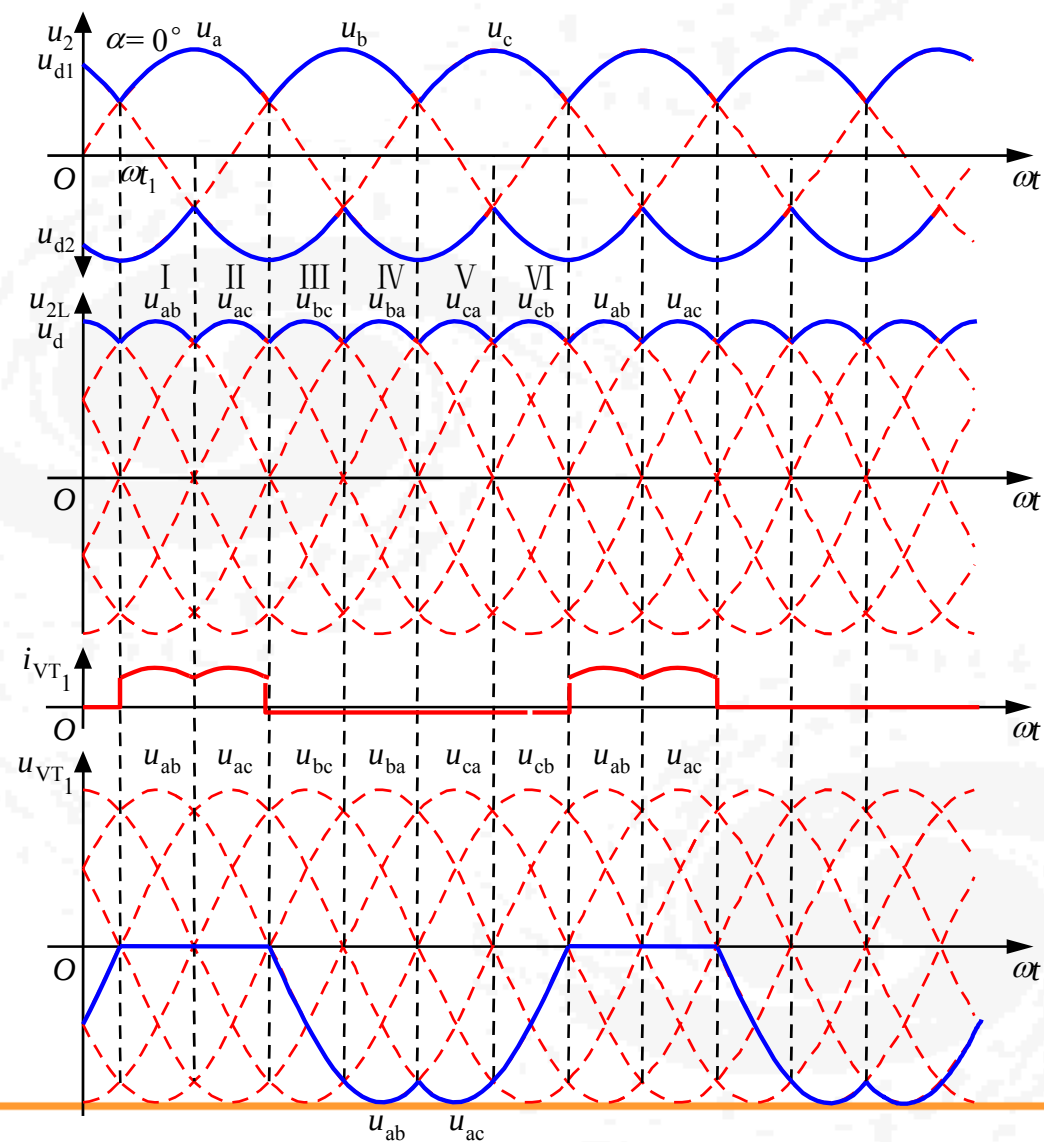
$$U_d = \frac{1}{\frac{2\pi}{3}} \int_{\frac{\pi}{6} + \alpha}^{\pi} \sqrt{2} U_2 \sin \omega t d(\omega t) = \frac{3\sqrt{2}}{2\pi} U_2 \left[1 + \cos\left(\frac{\pi}{6} + \alpha\right) \right] = 0.675 \left[1 + \cos\left(\frac{\pi}{6} + \alpha\right) \right]$$



Full Bridge SCR



$\alpha=0^\circ$

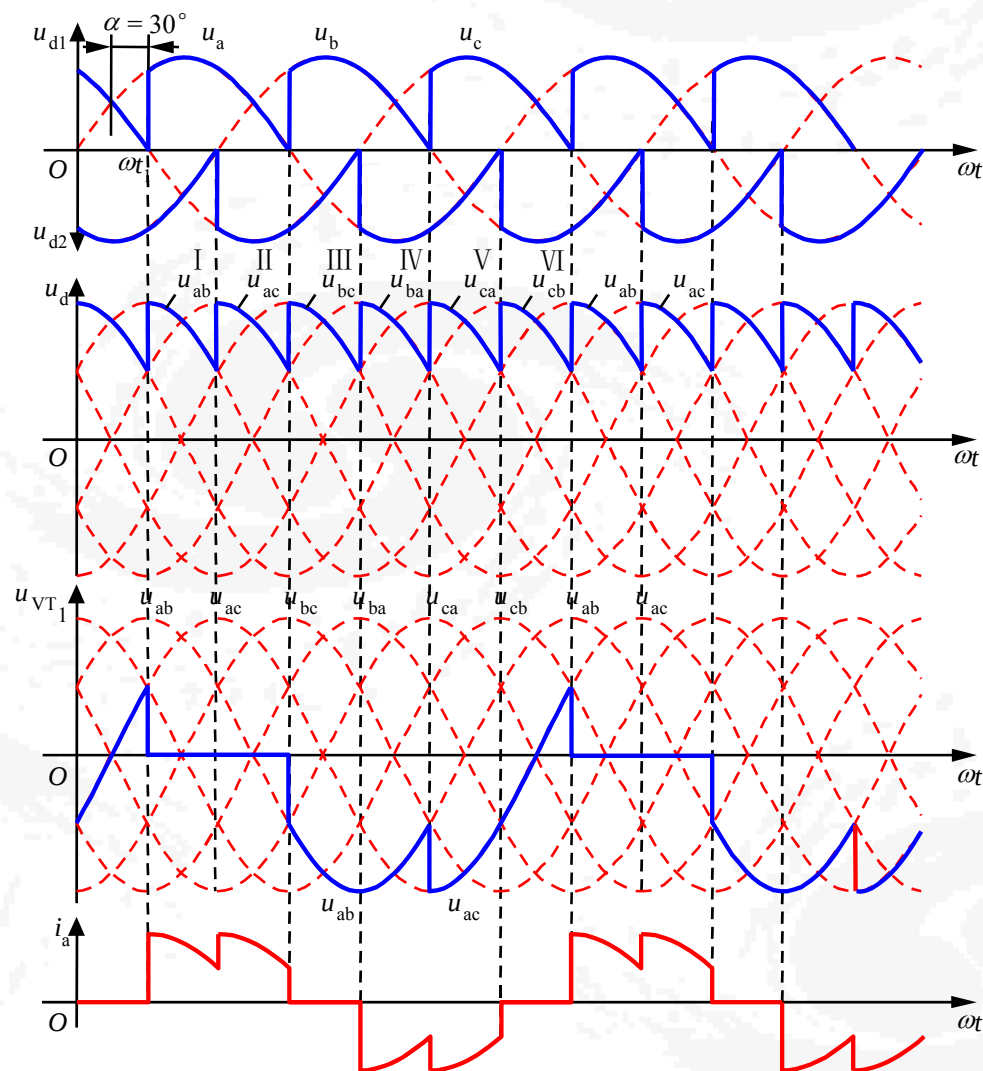


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$\alpha=30^\circ$

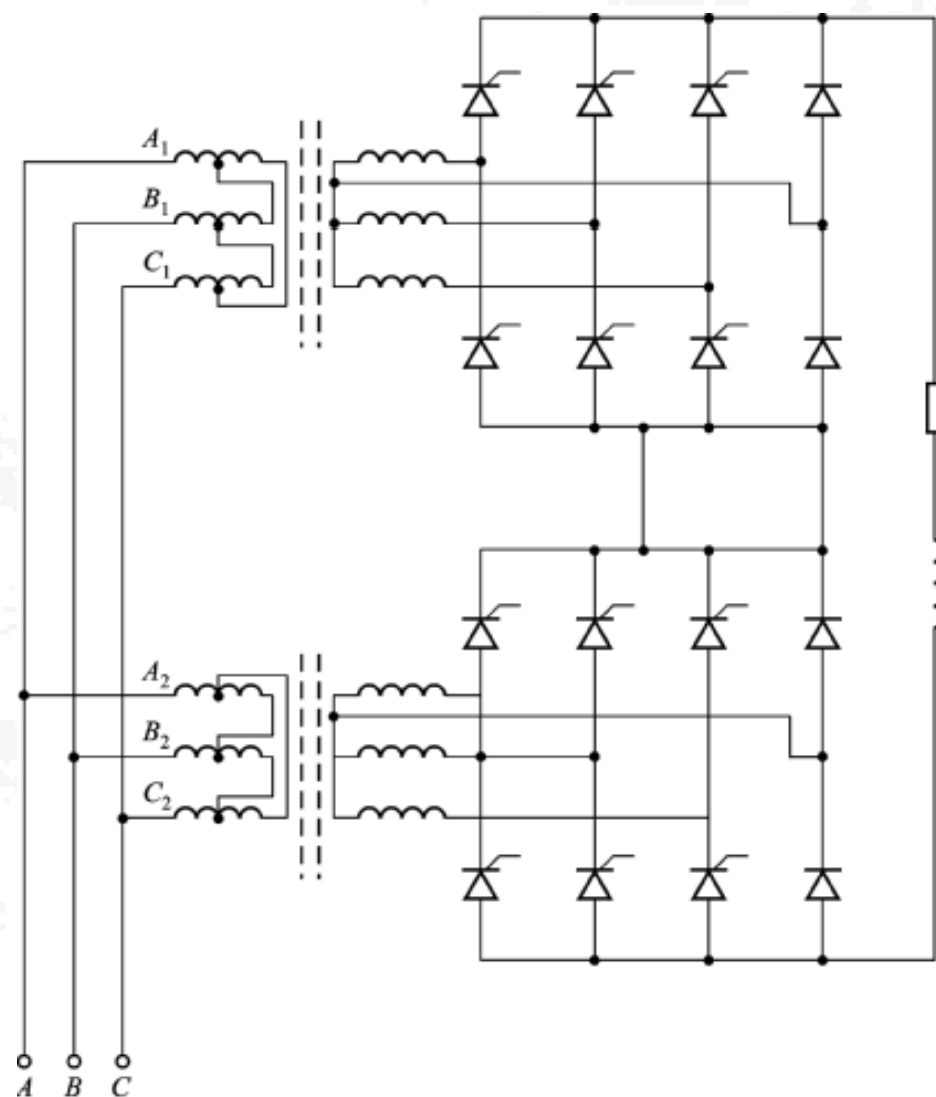


$$\alpha \leq 60^\circ$$

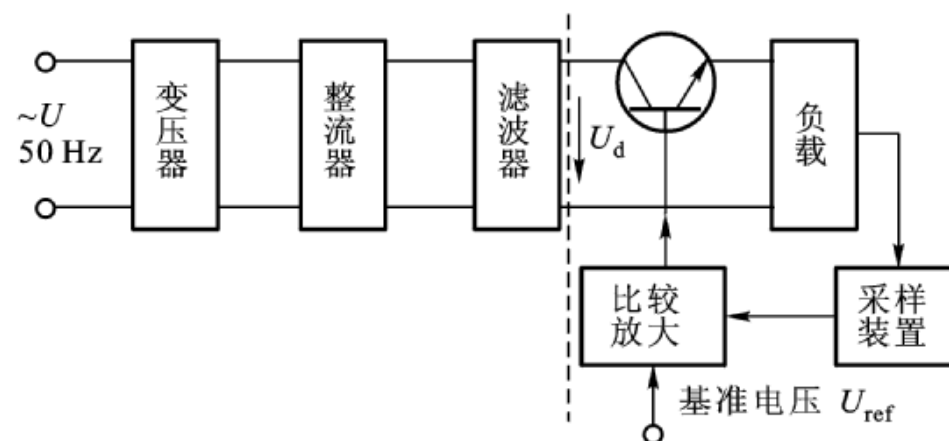
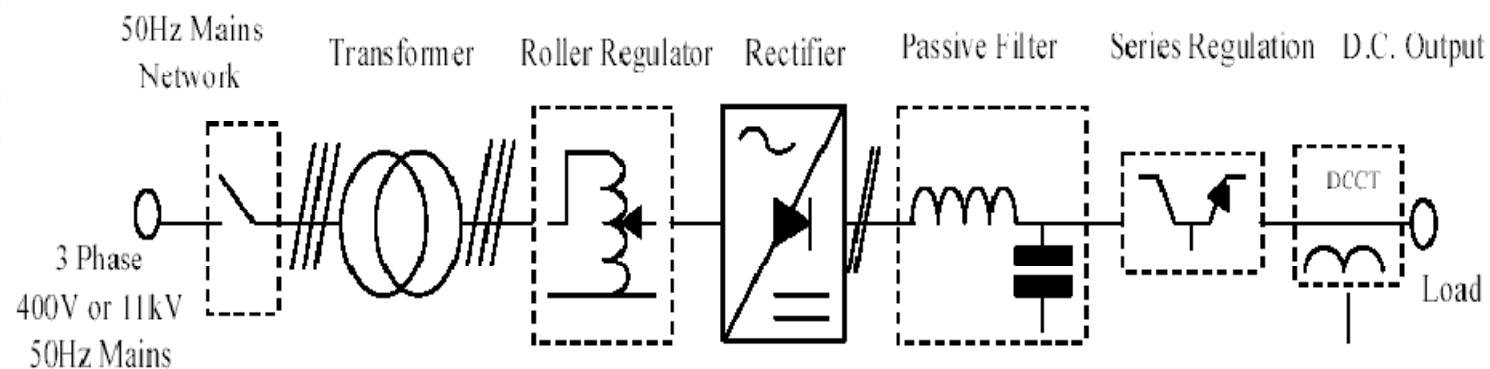
$$U_d = \frac{1}{\pi} \int_{\frac{\pi}{3} + \alpha}^{\frac{2\pi}{3} + \alpha} \sqrt{6} U_2 \sin \omega t d(\omega t) = 2.34 U_2 \cos \alpha$$

$$I_d = U_d / R$$





Line Regulation Power Supply



characteristic

➤ Advantage

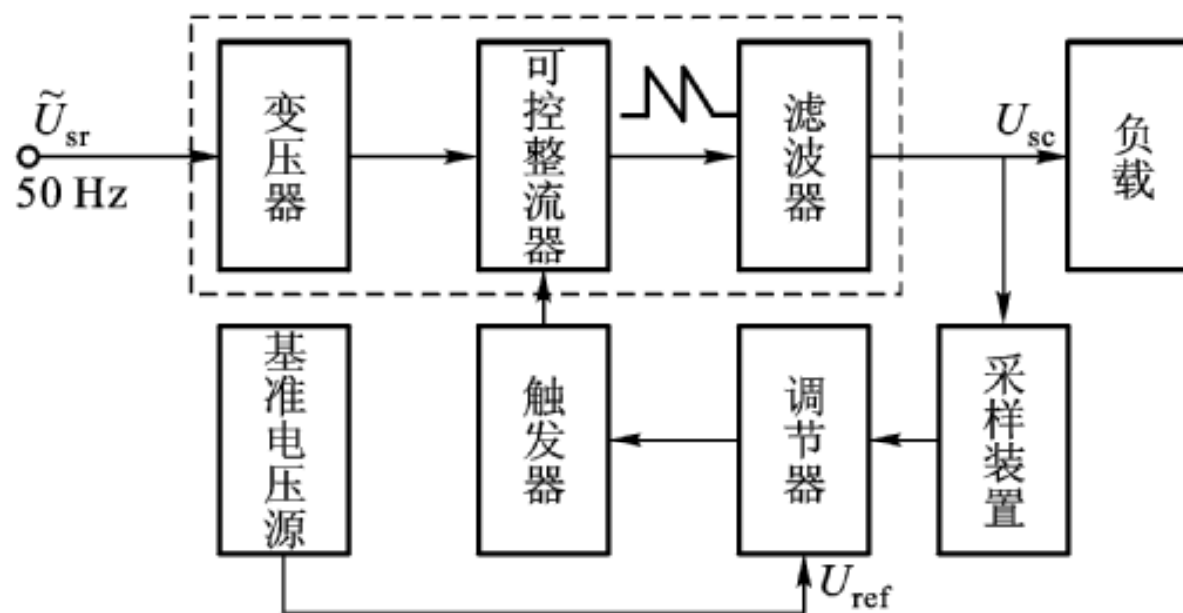
- Main circuit is simple;
- Fast dynamic;
- Low ripple;
- Low noise;

➤ Disadvantage

- Low efficient;
- Large value and weight;



SCR Power Supply



characteristic

➤ Advantage

- Main circuit is simple;
- Big power ratio;
- Noise;
- efficient;

➤ Disadvantage

- Large value and weight;
- High ripple;
- DC;

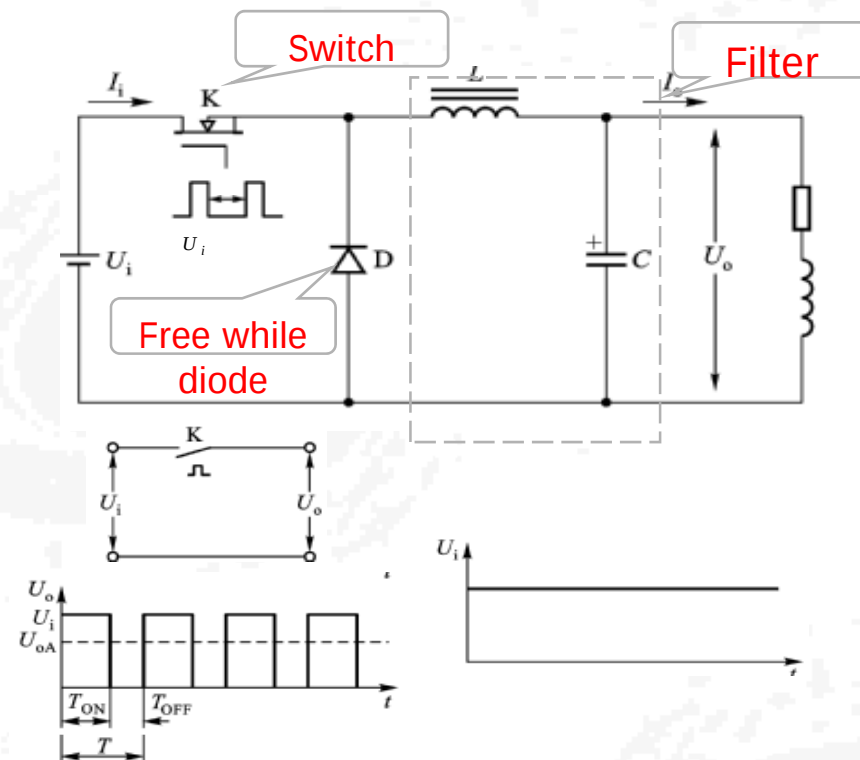


Switch Mode Power Supply

- **PWM : Pulse Width Modulation;**
- **IGBT, MOSFET...;**



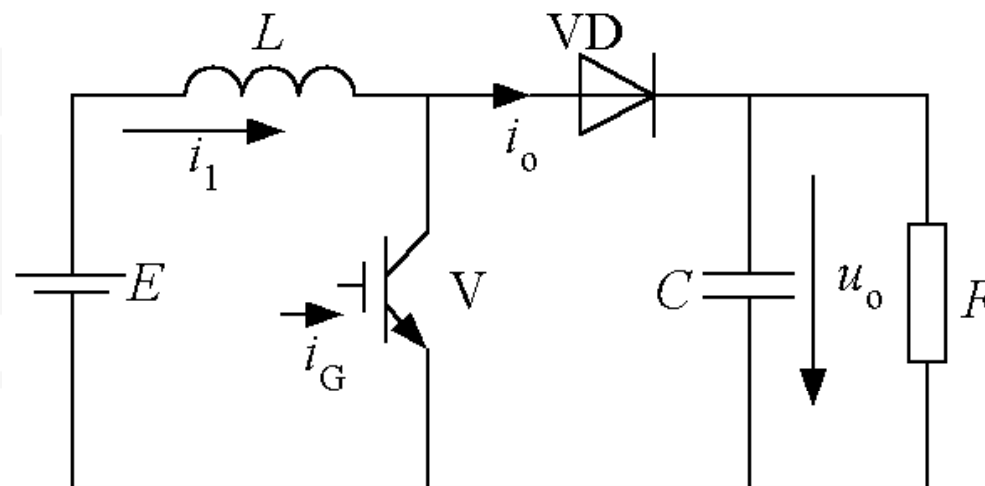
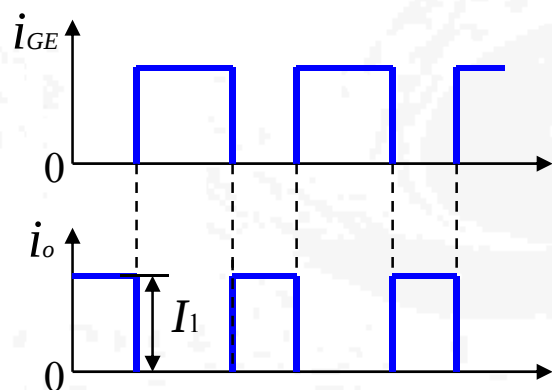
Buck



$$U_o = \frac{t_{on}}{t_{on} + t_{off}} E = \frac{t_{on}}{T} E = \alpha E$$



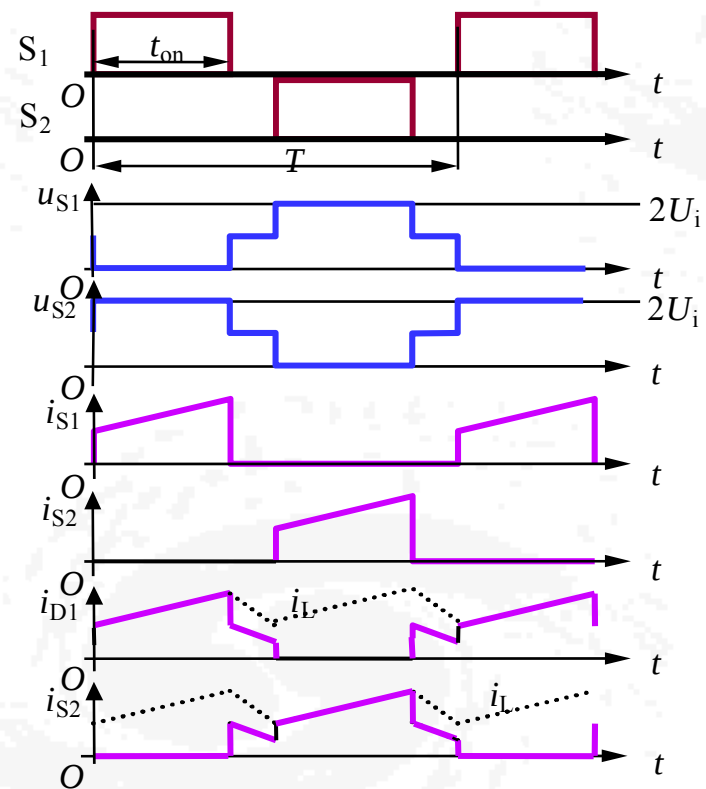
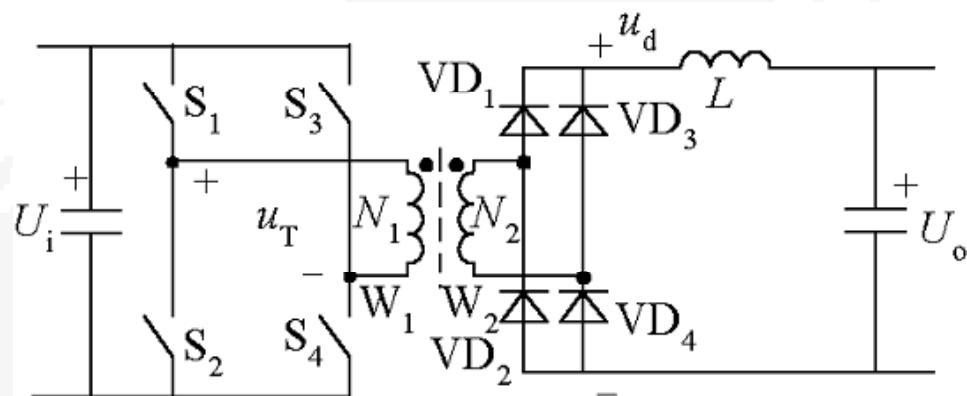
Booster



$$U_o = \frac{t_{\text{on}} + t_{\text{off}}}{t_{\text{off}}} E = \frac{T}{t_{\text{off}}} E$$



Full Bridge



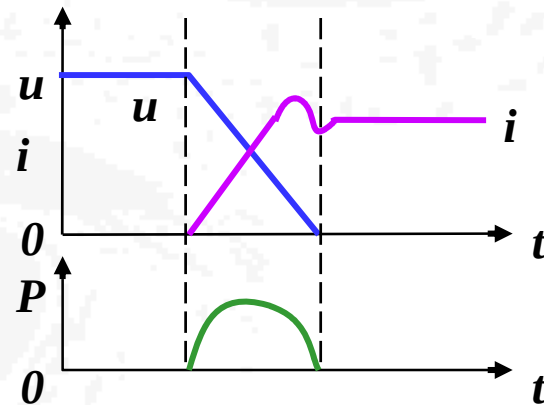
Characteristic

- **Advantage**
 - **High efficiency;**
 - **Small value and weigh;**
 - **Low ripple;**
 - **Fast dynamic;**
- **Disadvantage**
 - **EMI;**
 - **High price;**

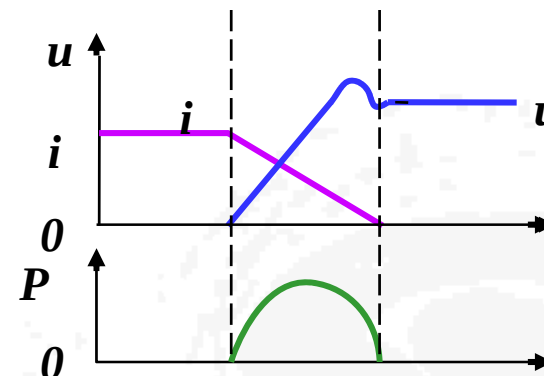


Soft switch

➤ Why soft switch



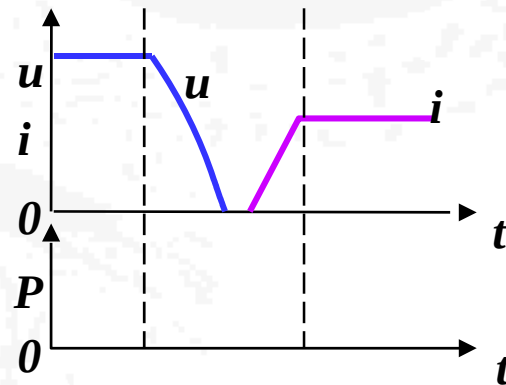
a) hard switch on



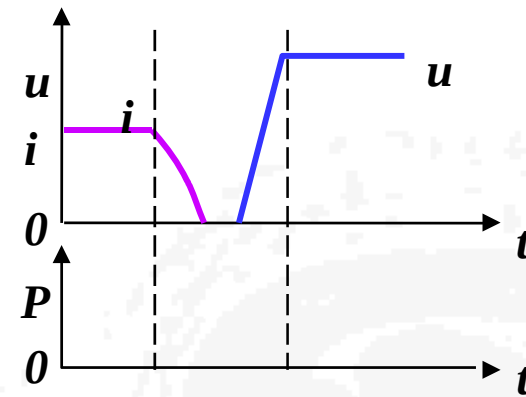
b) hard switch off



➤ Zero voltage Switch and Zero current Switch



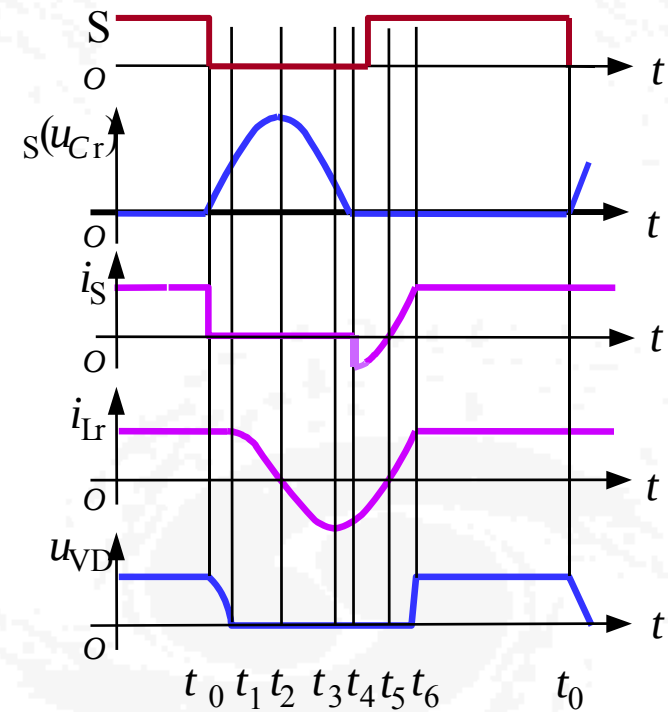
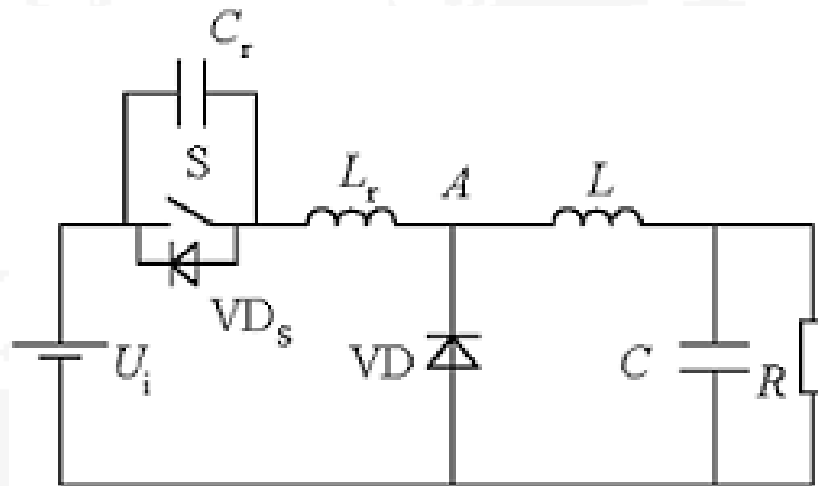
a) Soft switch on



b) soft switch off



Zero Voltage Switch



- Power components;
- Power supply classification;
- **Power supply parameters definitions;**
- Regulation Loop;
- CSNS PS system;



Some definitions

- **PPM: Part Per Million** = $10^{-6} = 2^{-20}$ (20 bits);
- **Nominal value** (I_{Nominal}): Normal maximum value;
- **ppm of nominal**: $10^{-6} \times I_{\text{Nominal}}$ (Amp);

Example: $I_{\text{nominal}} = 1000\text{A}$, 1ppm of nominal = 1mA.



Precision

– Accuracy

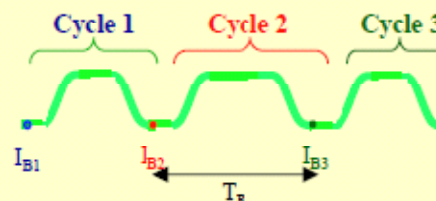
Long term setting or measuring uncertainty taking into consideration the full range of permissible changes* of operating and environmental conditions.

* requires definition



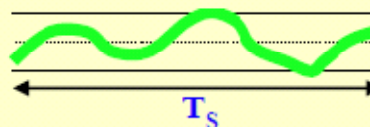
– Reproducibility

Uncertainty in returning to a set of previous working values from cycle to cycle of the machine.



– Stability

Maximum deviation over a period with no changes in operating conditions.

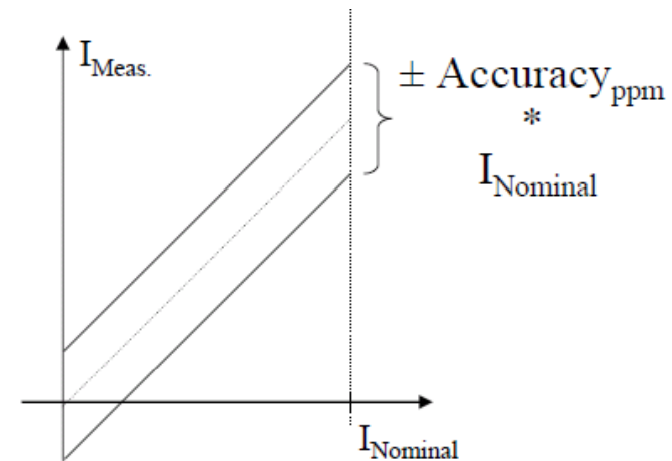


Accuracy, reproducibility and stability are defined for a given period



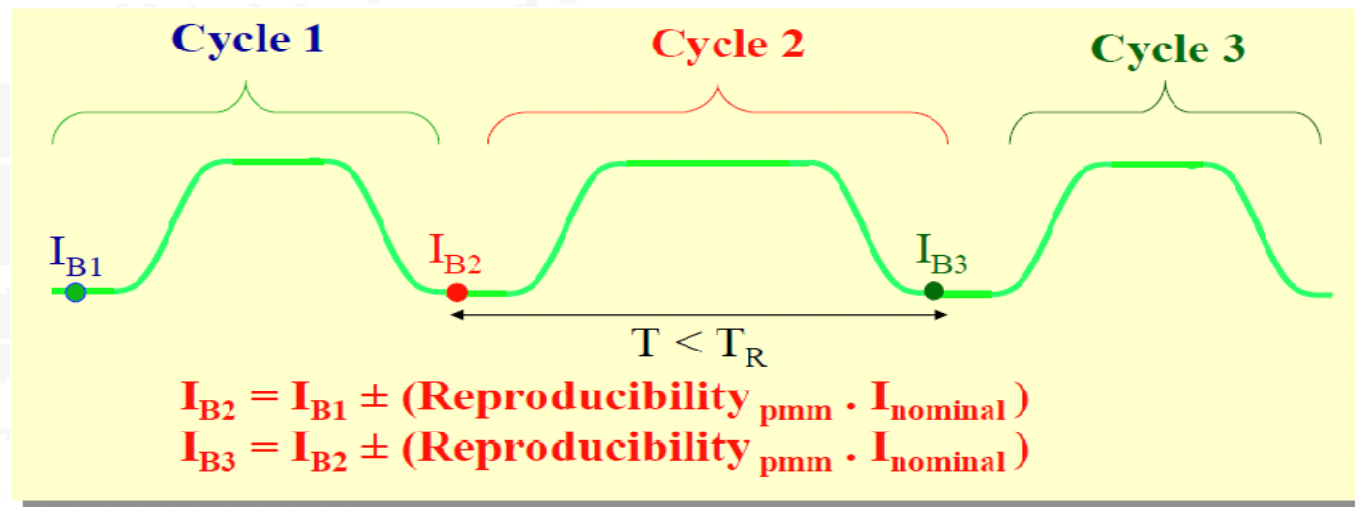
Accuracy

- Long term setting or measuring, uncertainty taking into consideration the full range of permissible change in operating and environmental conditions;
- Requires definition: Electrical distribution system perturbation, temperature variation,...
- The accuracy is defined by default for a defined period, such as one year, one month, 24 hours...
- The accuracy is expressed in ppm of I_{Nominal} .
- If the define period is too large, a calibration process should be executed more often.



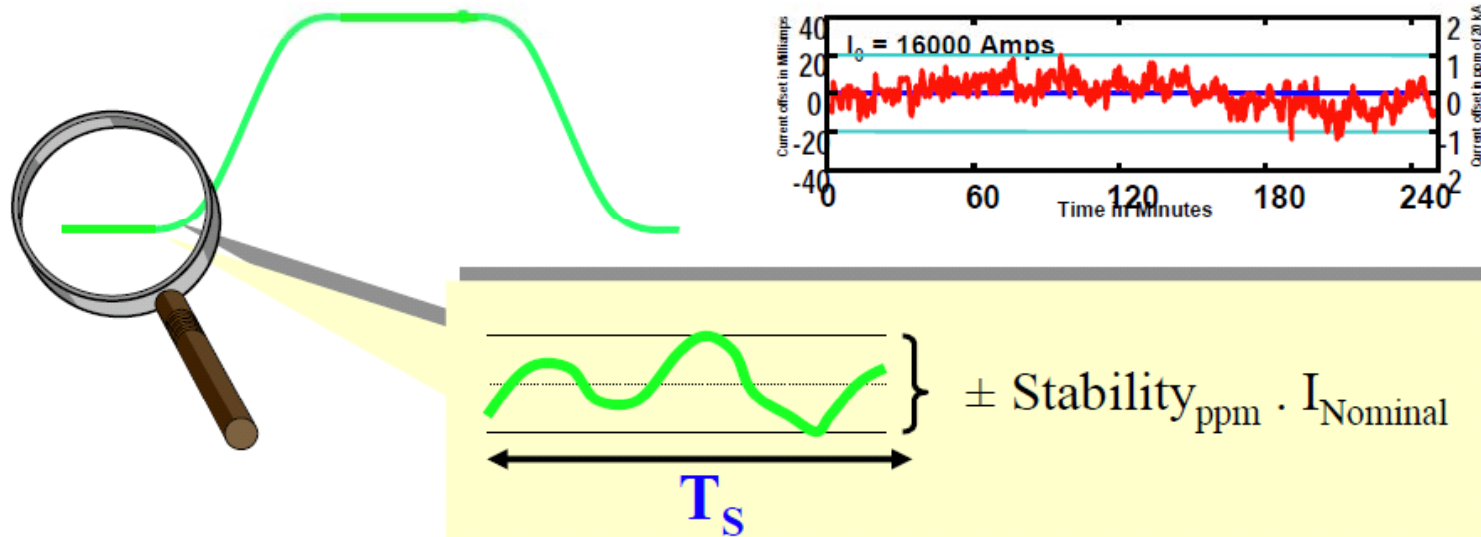
Reproducibility

- Uncertainty in returning to a set of previous working values from cycle to cycle of the machine;
- The reproducibility is defined by default for a period of time T_r without any intervention affecting the calibrated parts (DCCT, ADC.....)
- The reproducibility is expressed in ppm if I_{Nominal} .



Stability

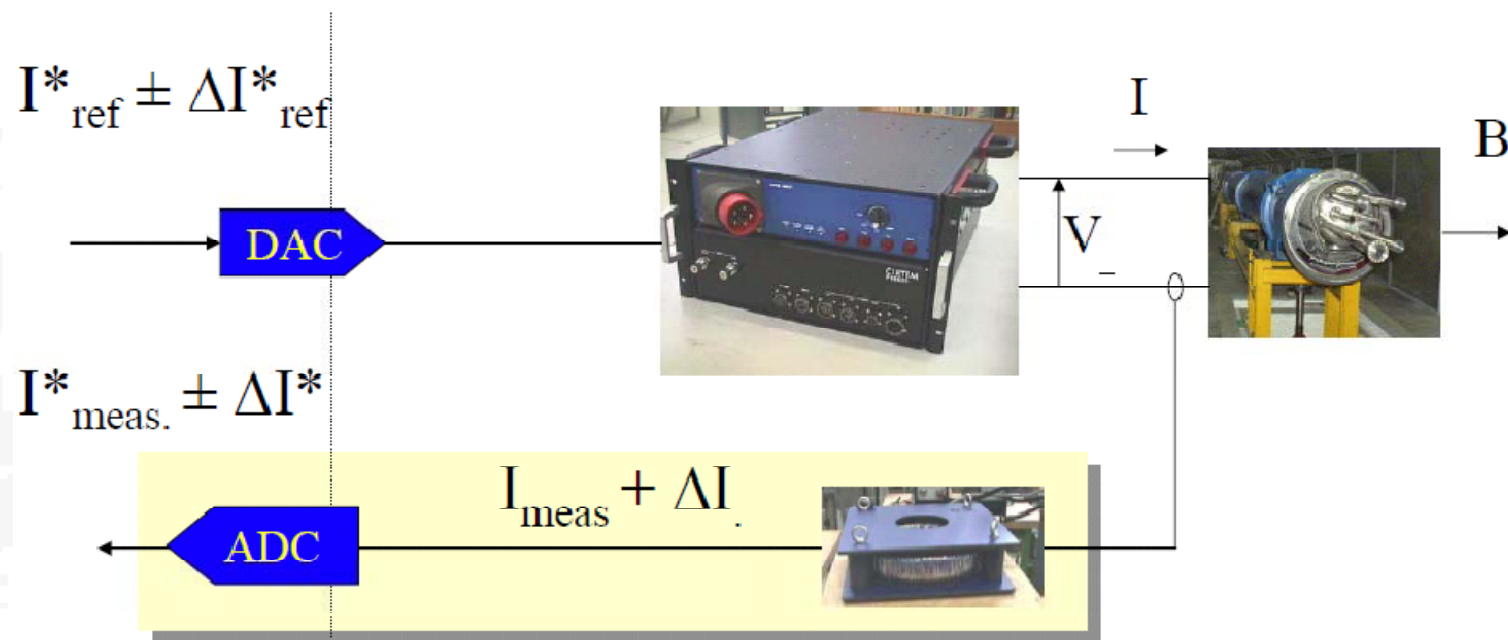
- Maximum deviation over a period with no changes in operating conditions;
- The stability is defined by default for a period of time T_s
- The stability is expressed in ppm of I_{Nominal}



Resolution

Smallest increment that can be induced or discerned.

The resolution is expressed in ppm of I_{Nominal} .
Resolution is directly linked to A/D system

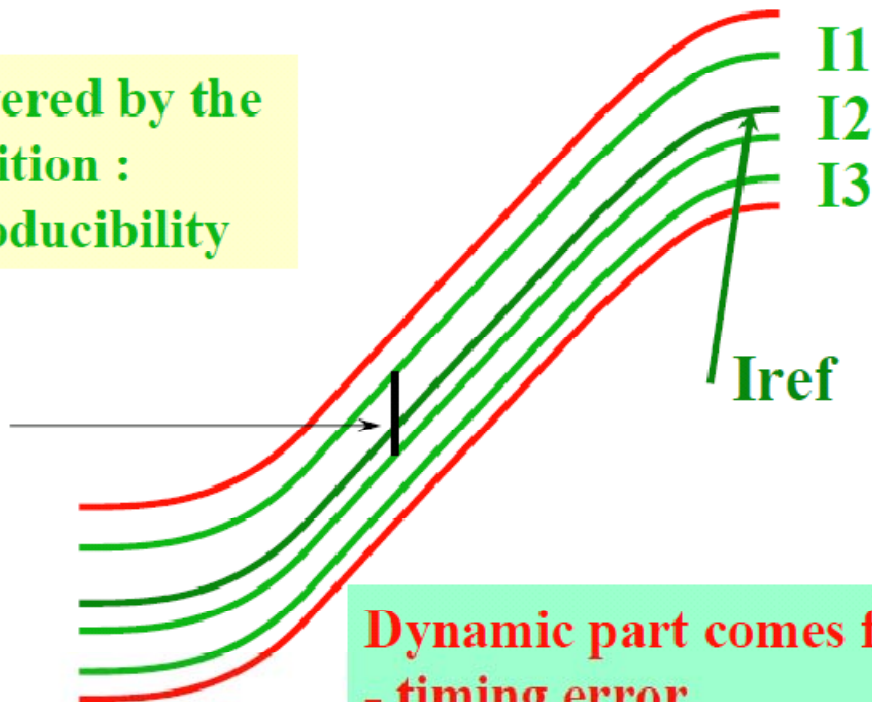


Tracking

- Ability of the power supply to follow the reference function (static, dynamics);

Static part is covered by the static definition :
accuracy, reproducibility

Tracking error
between I1 and I2

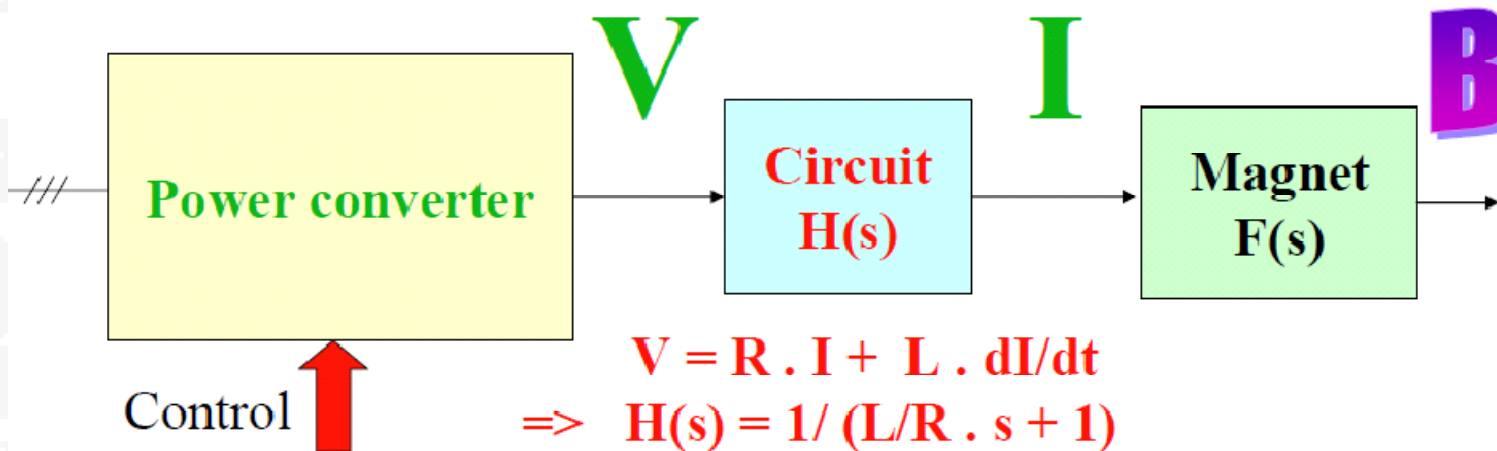


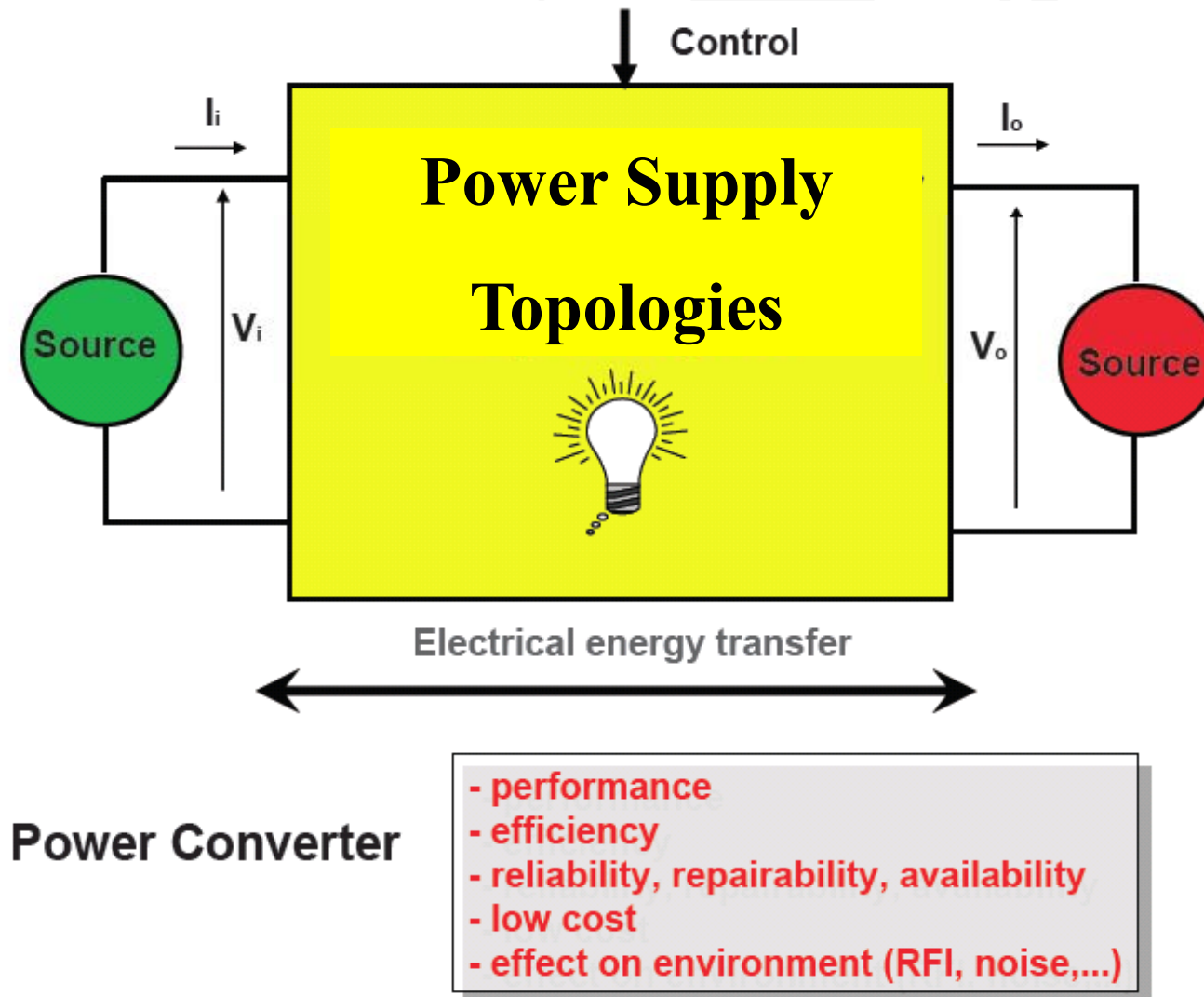
Dynamic part comes from :
- timing error
- lagging error in the regulation

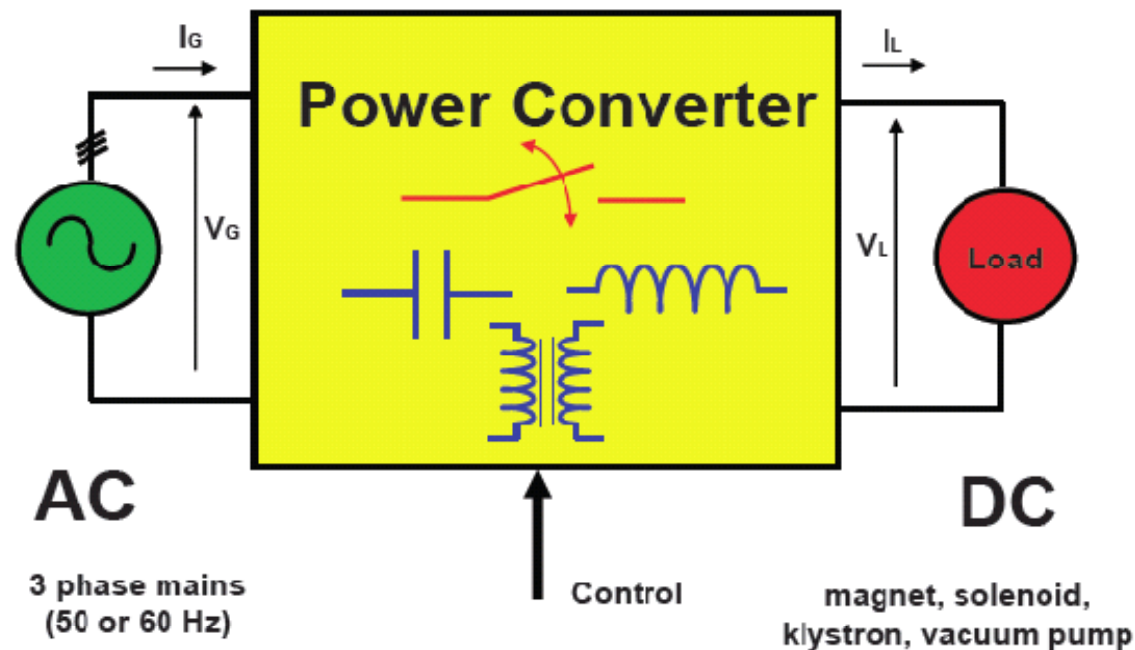


Ripple

- Voltage ripple is defined by power supply;
- Current ripple: load transfer function (cable, magnet inductance,...)







- low mains harmonic distortion
- power factor (closest to 1)

- low ripple (current)
- reproducibility (short and long term)
- rejection of mains disturbance
- dynamic response

Achieving high performance : **COMPROMISE**

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How do the stability and the accuracy of the Power Supplies affect the accelerator?

- Accuracy of the energy of the beams: dipoles;

$$E_0 = \rho_s * e * c * B_0$$

- Modify the turns of the machine: quadrupoles;

$$\Delta \nu = -\frac{1}{4\pi} \beta_n \Delta K \Delta S$$

- Perturb the closed orbit of the machine: field errors/fluctuations.

The stability and the accuracy of the power supplies is one of the key ingredients to ensure the expected performance of the machine!



- Power components;
- Power supply classification;
- Power supply parameters definitions;
- **Regulation Loop;**
- CSNS PS system;



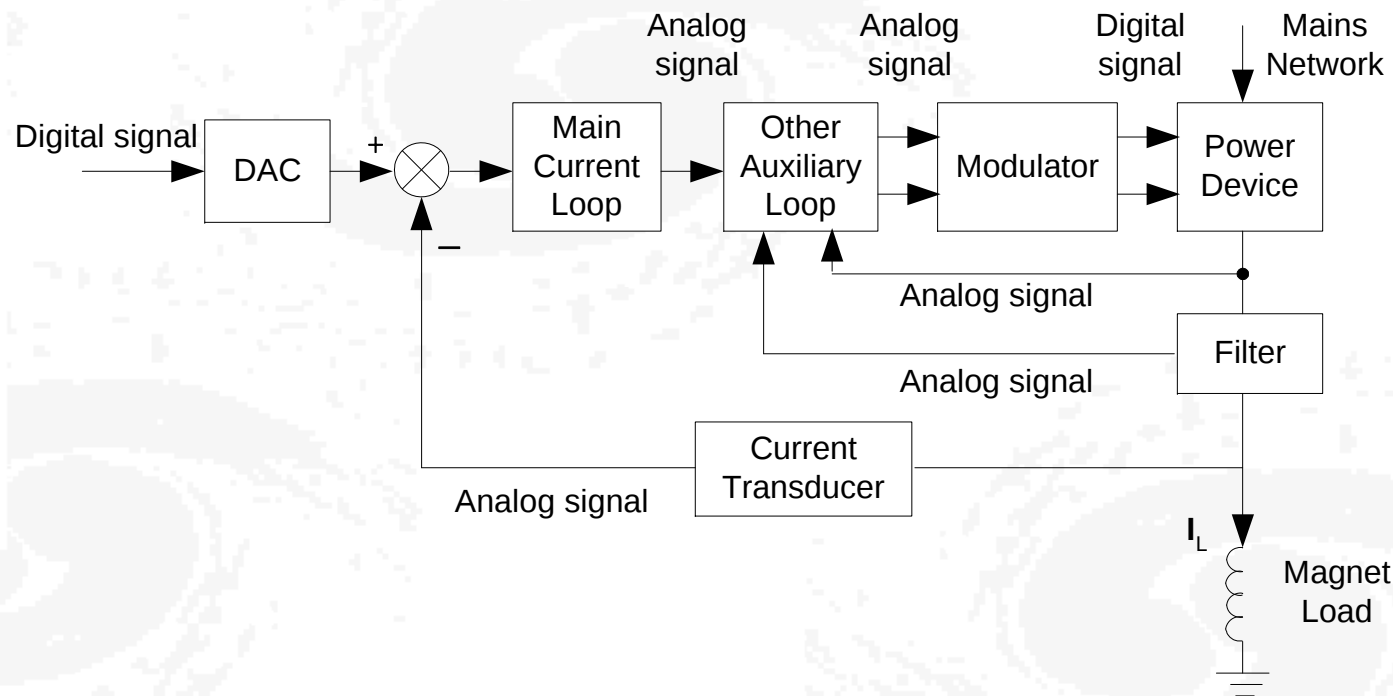
Controller Design

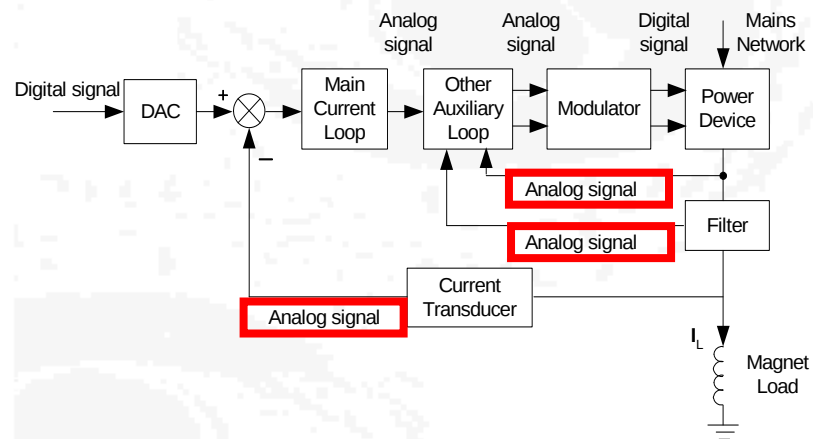
In order to design and tune a controller:

- To specify the desired closed control loop performance:
 - Regulation and tracking: rise time and max overshoot or bandwidth and resonance
- To choose a suitable controller design method
- To know the dynamic model of the plant to be controlled → control model

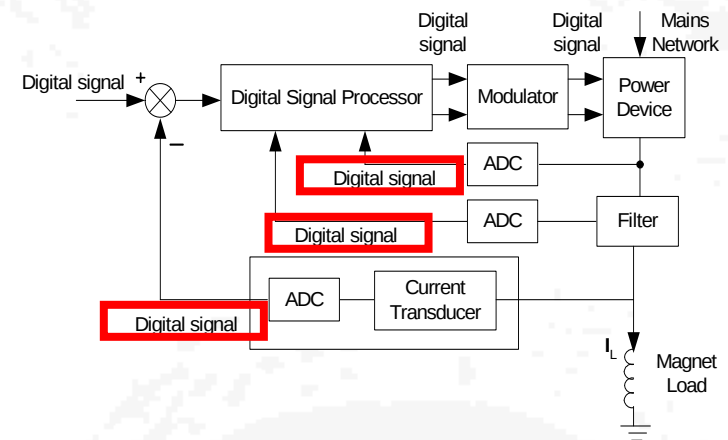


Control Loop





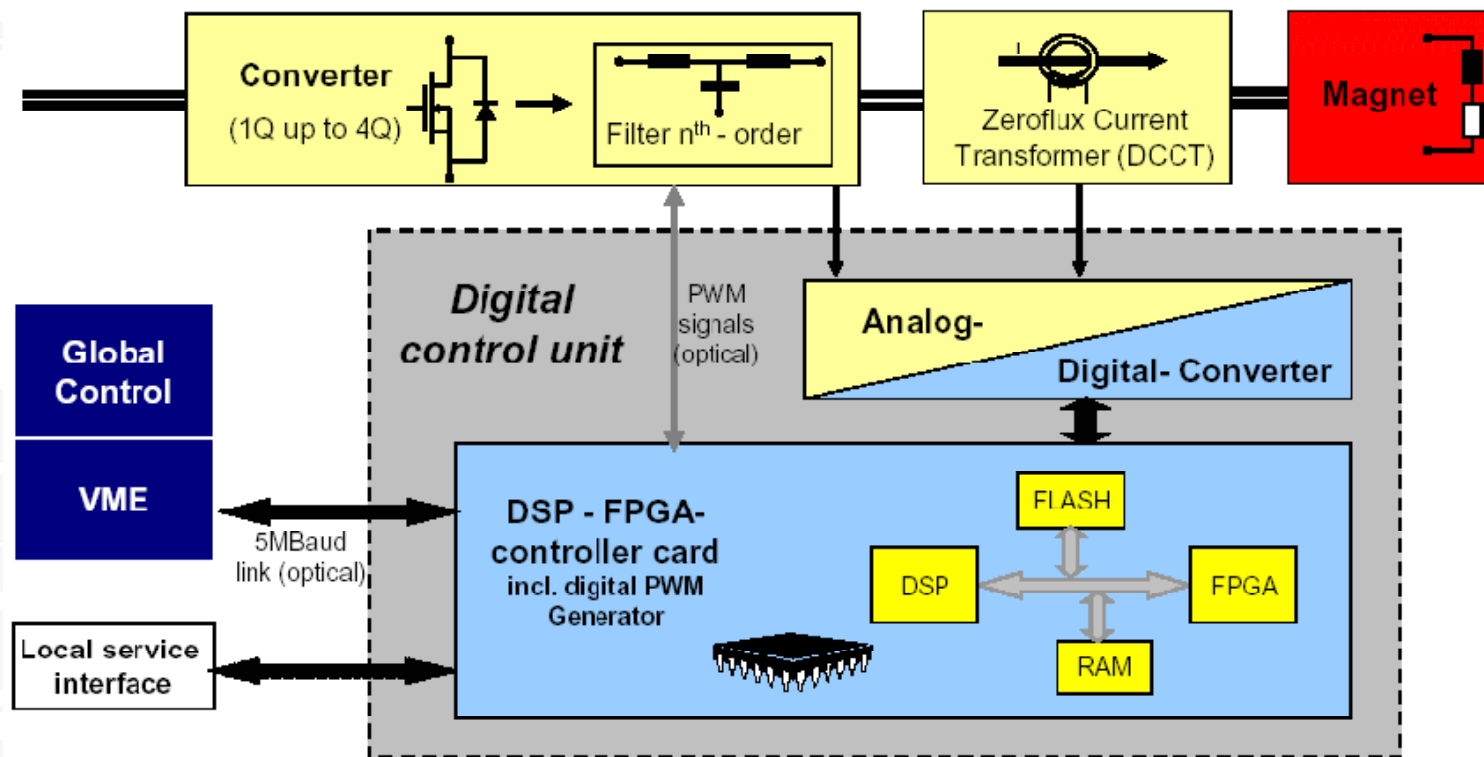
Analog control loop



Digital control loop



SLS Digital controller



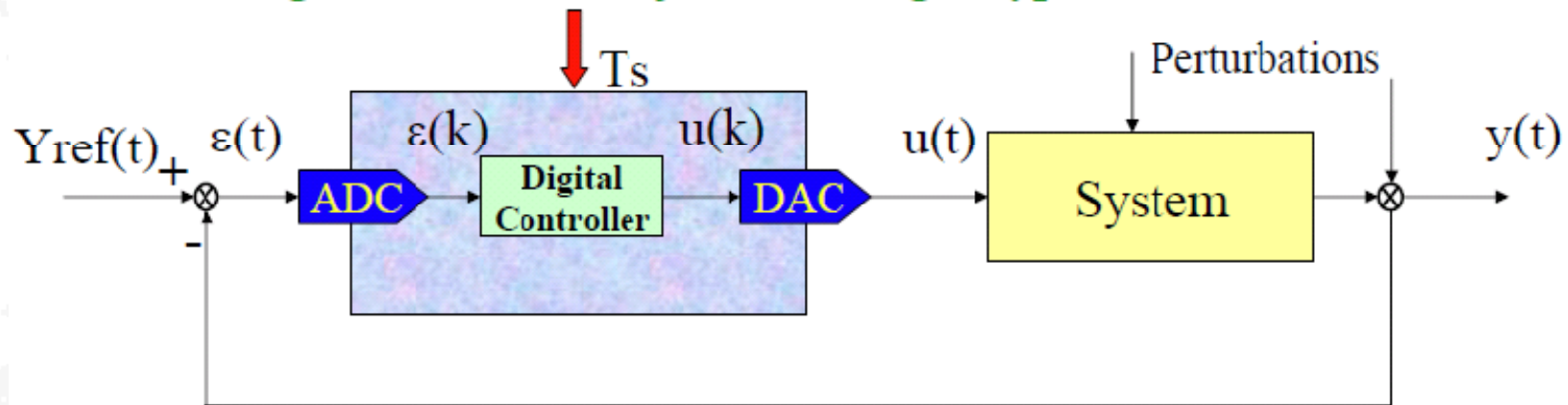
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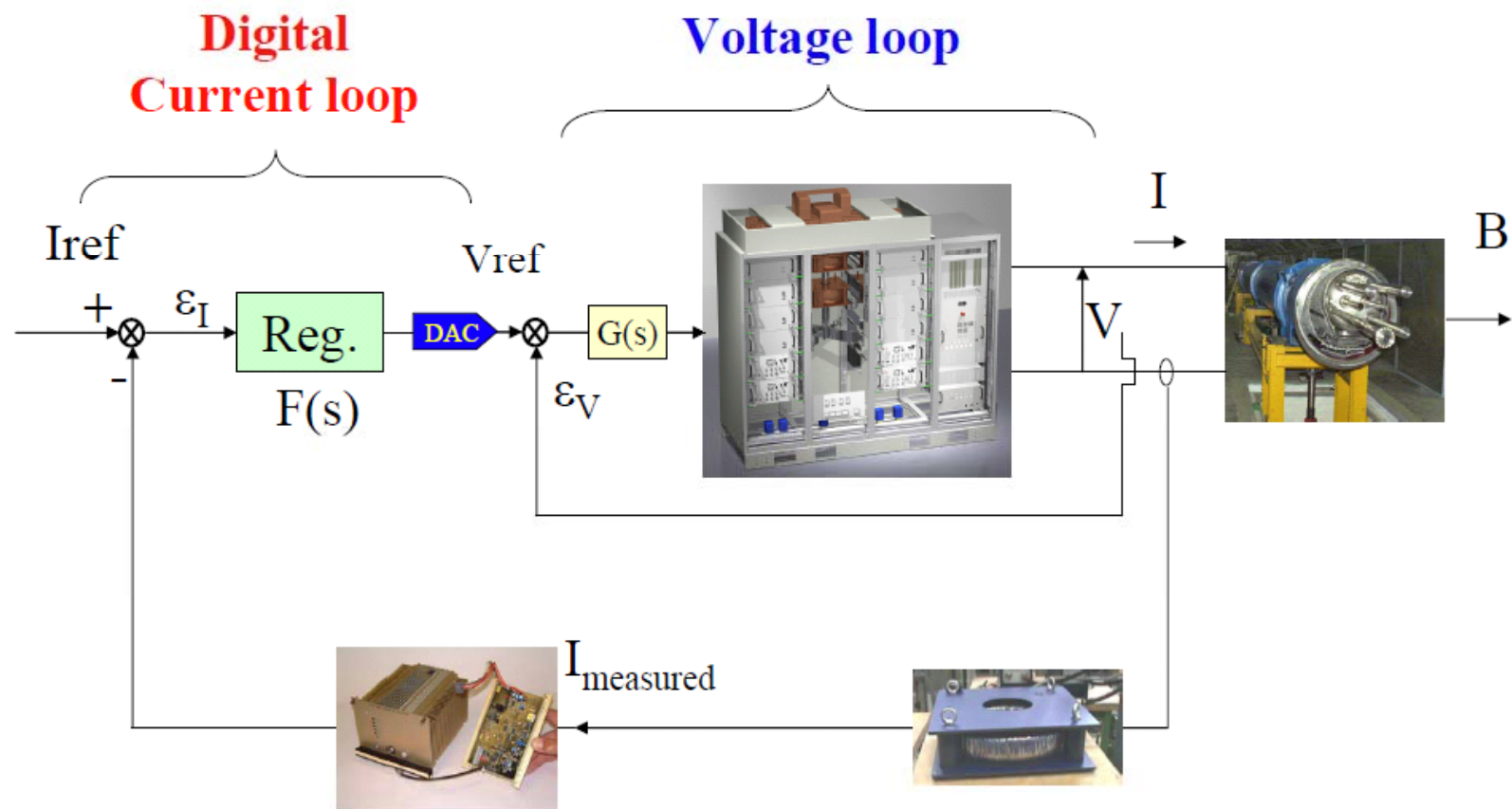
LHC

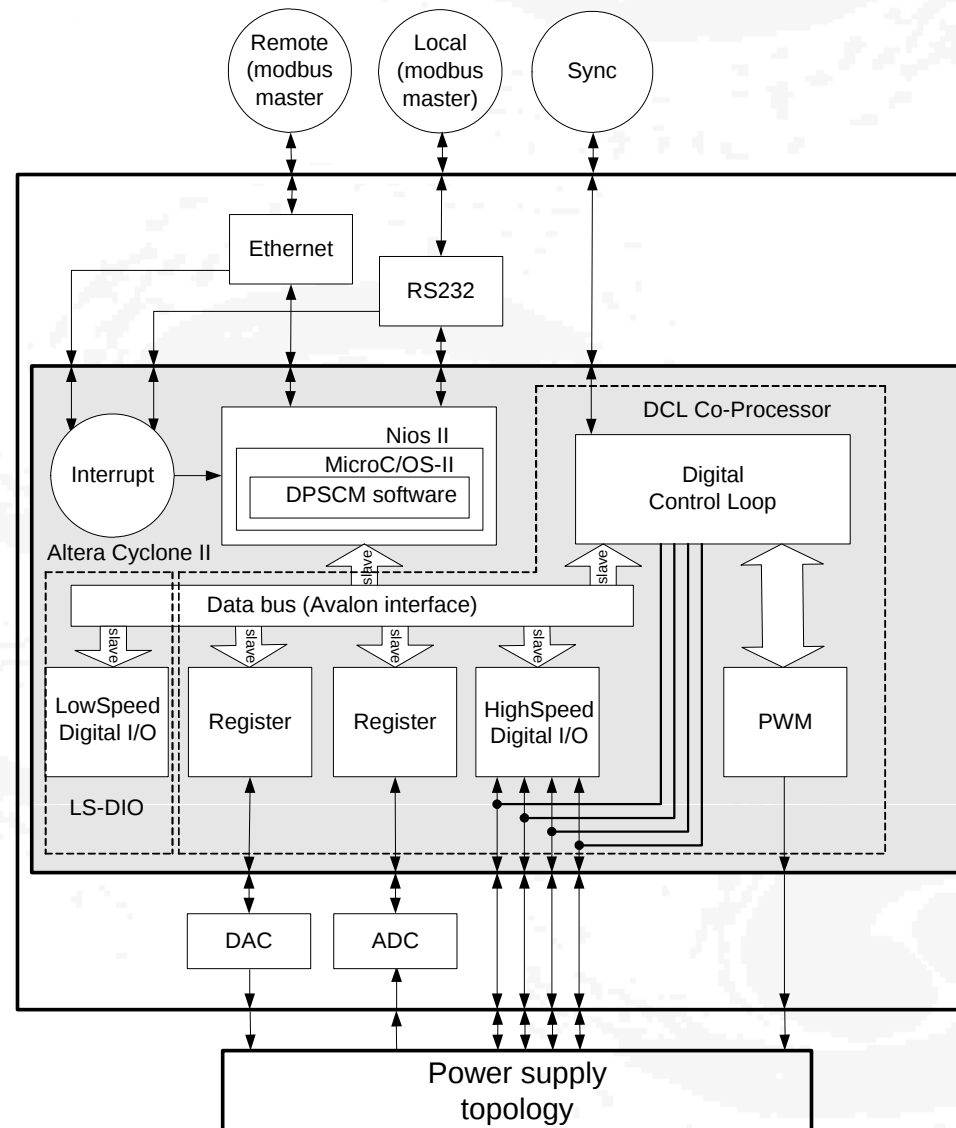
Digital realisation of an “analogue type” controller



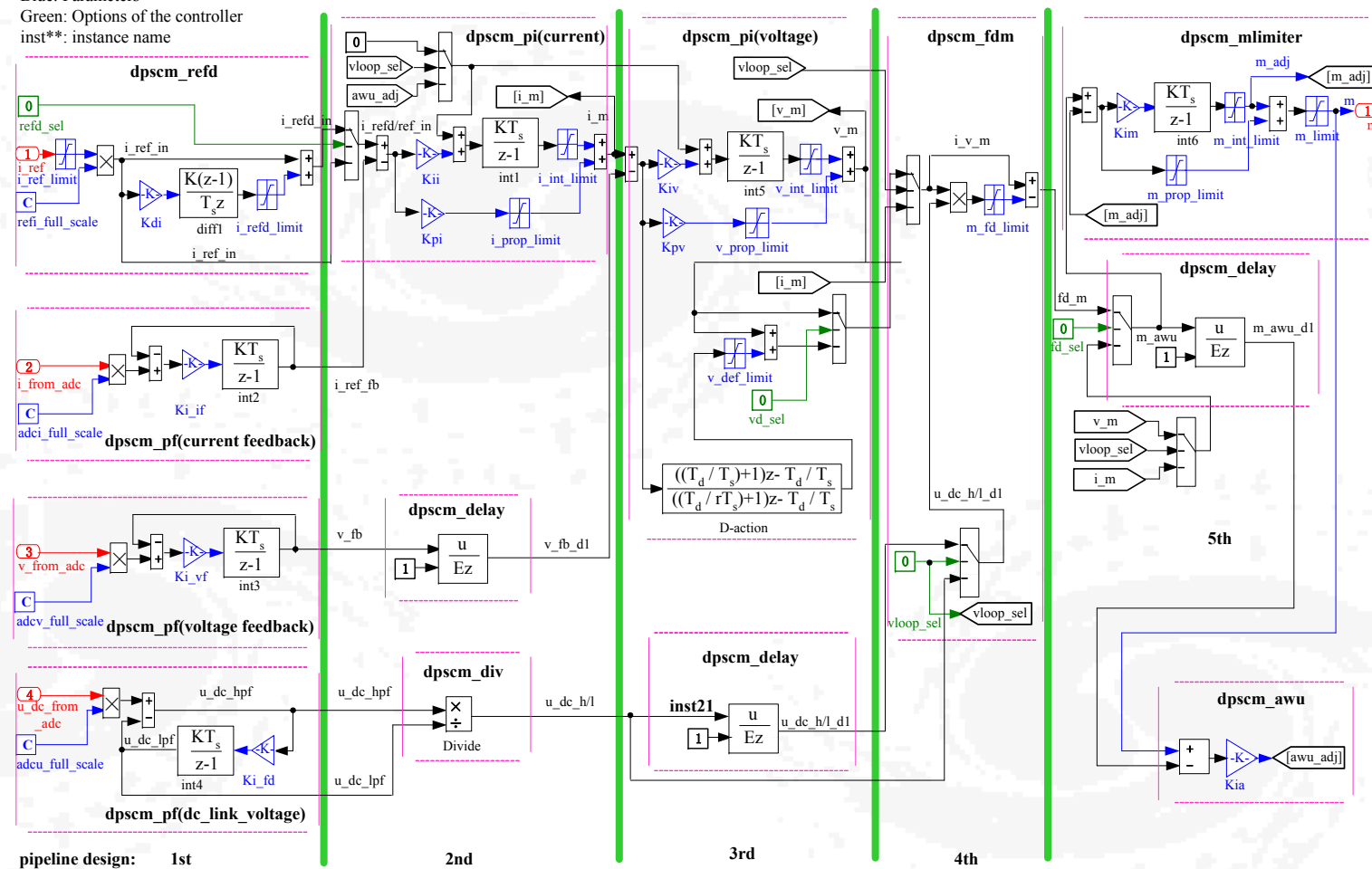
ADC- Digital controller - DAC should behave the same as an analogue controller (e.g. PID type), which implies **the use of a high sampling frequency** (the algorithm implemented is very simple)





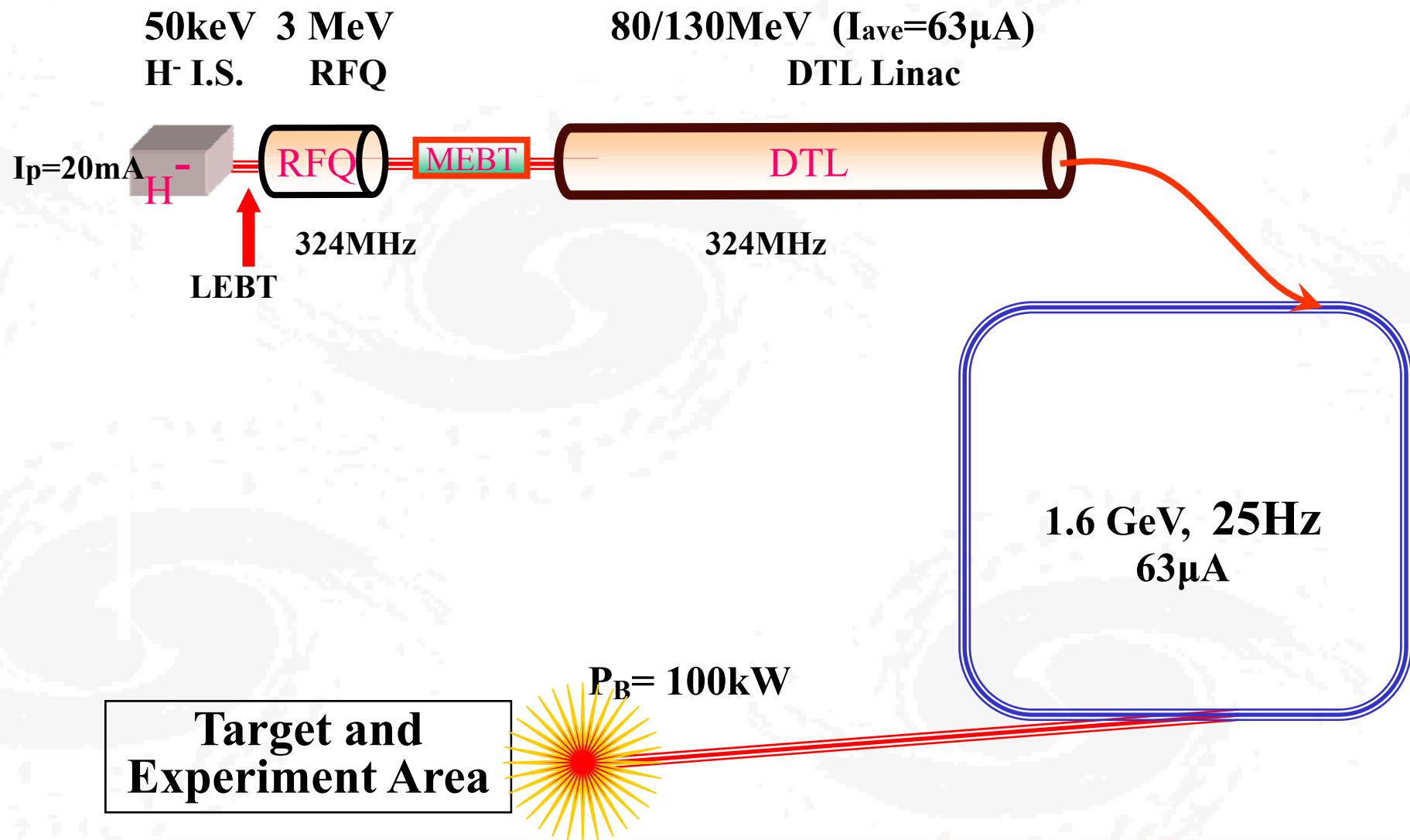


Red: Input and Output
 Blue: Parameters
 Green: Options of the controller
 inst*: instance name



- Power components;
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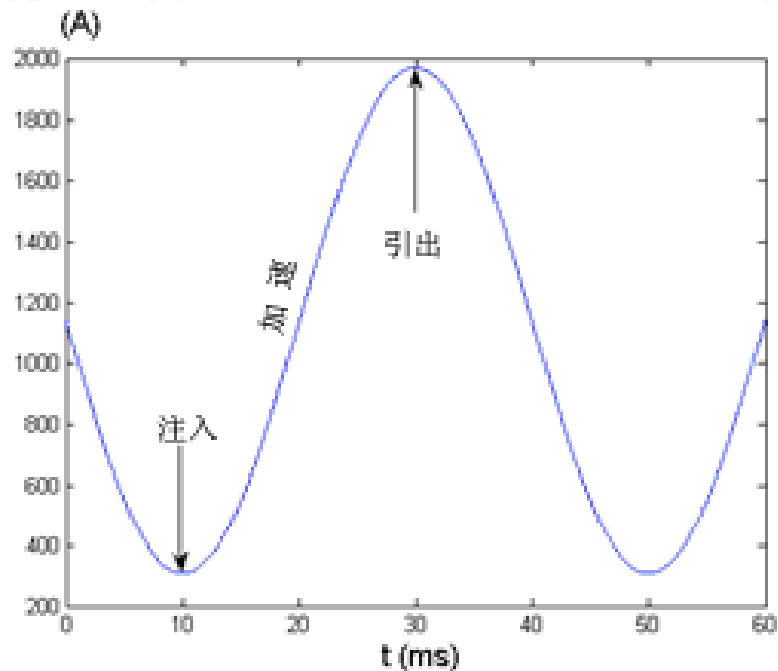


- **RCS:**
 - **Multi-mesh White circuit:**
 - One dipole power supply**
 - 5 quadrupole power supplies**
 - **Large dynamical system**
 - Total input power rating:**
 - BMPS 3.2MW, QMPS 4.5MW**
 - **Repeating rate:**
 - 25HZ, DC biased sine waveform**
- **Others: DC Power Supplies.**



White circuit parameters

- Magnet current: $I_m = I_{DC} - I_{AC} \sin(\omega t)$
- Magnet voltage: $V_m = R_m I_m - \omega I_{AC} L_m \cos(\omega t)$
- Choke inductance:
 $L_{ch} = L_m$
- Choke current:
 $I_{ch} = I_{DC} + I_{AC} \sin(\omega t)$
- Peak magnet energy:
 $E_m = (1/2) L_m (I_{DC} + I_{AC})^2$

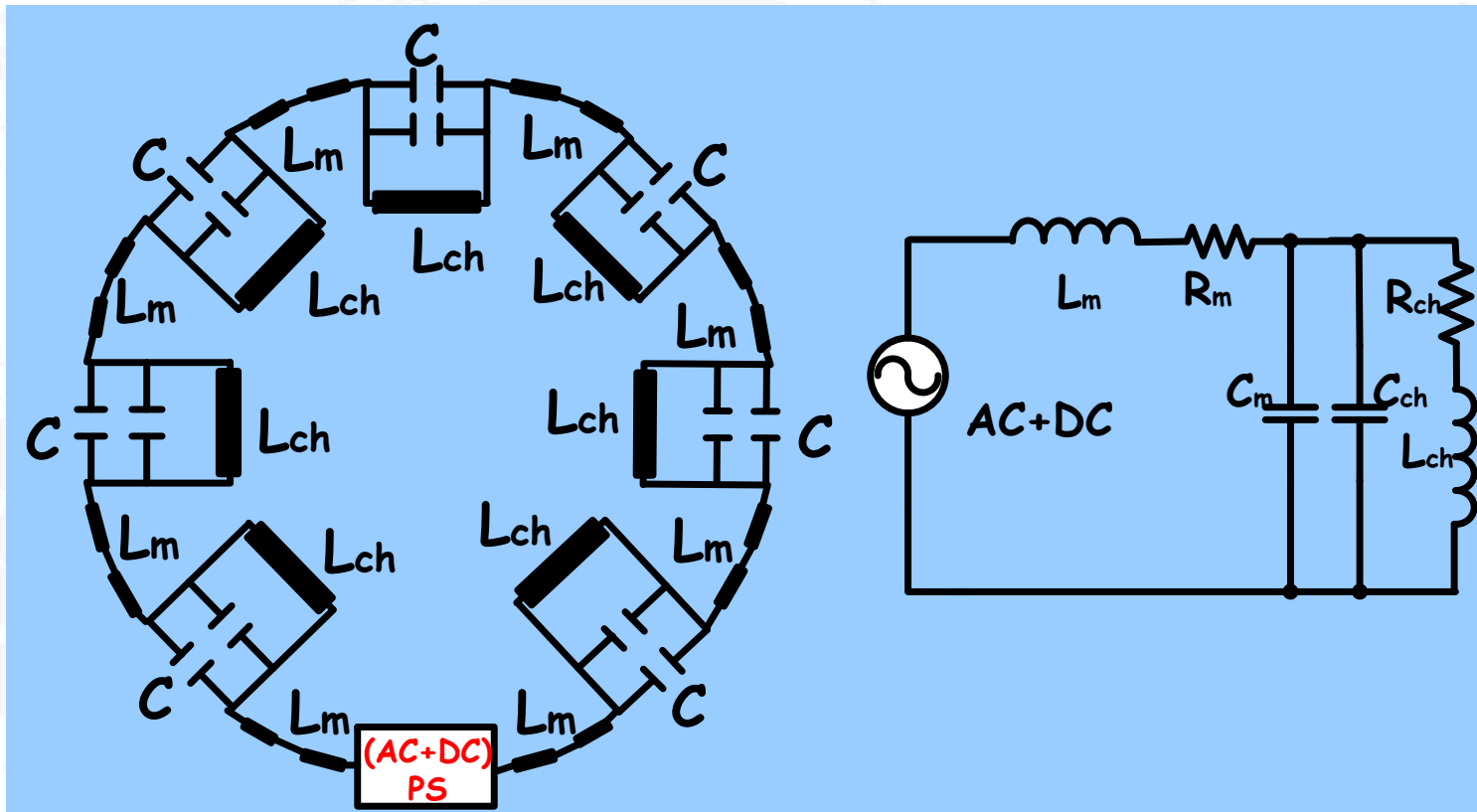


Main Power Supply of RCS/CSNS

Power Supply		I_N (A)	V_N (V)	P_{avr} (kW)		magnet
RCS-BPS	1	2200	6000	3108	160B	24
RCS-QPS1	1	1393	828	598	206Q	8
RCS-QPS2	1	1484	3700	2036	265Q	16
RCS-QPS3	1	1393	828	598	206Q	8
RCS-QPS4	1	1226	800	484	222Q	8
RCS-QPS5	1	1419	1400	754	253Q	8



Serial resonant network



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Resonant Component parameter

	BPS	QPS1	QPS2	QPS3	QPS4	QPS5
Magnet	24	8	16	8	8	8
Magnet No./cell	2	8	4	8	8	8
Cell No.	12	1	4	1	1	1
L_{MAGNET} (mH)	38.8	8.69	24.88	8.69	9.33	17.33
C_m (μF)	1045.6	1167.1	815.3	1167.1	1087.1	585.3
L_{CH}(mH)	77.6	69.52	99.52	69.52	74.64	138.64
Voltage_{p-p}(V)	10624	6327	9651	6327	5976	12856





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Choke



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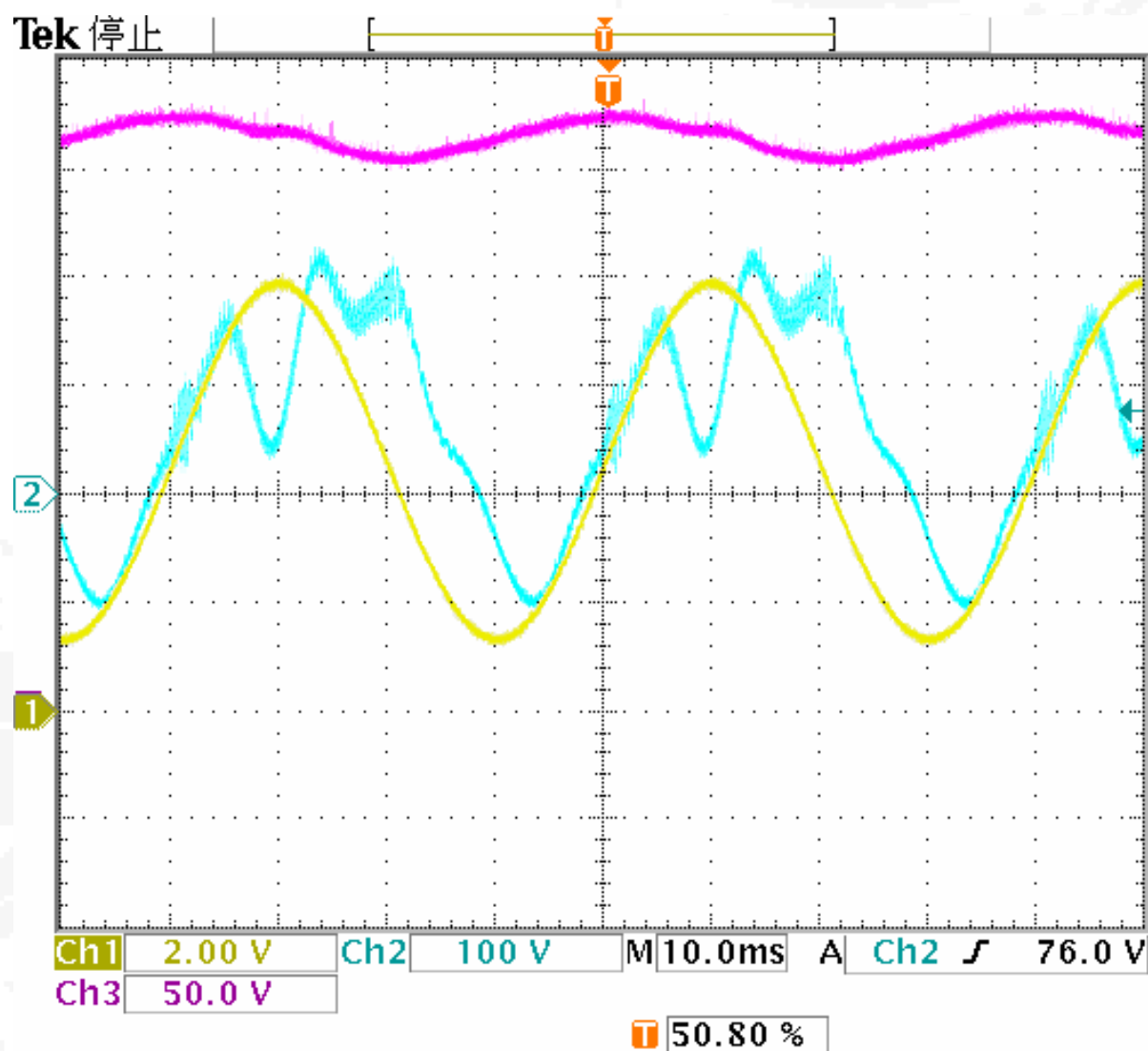




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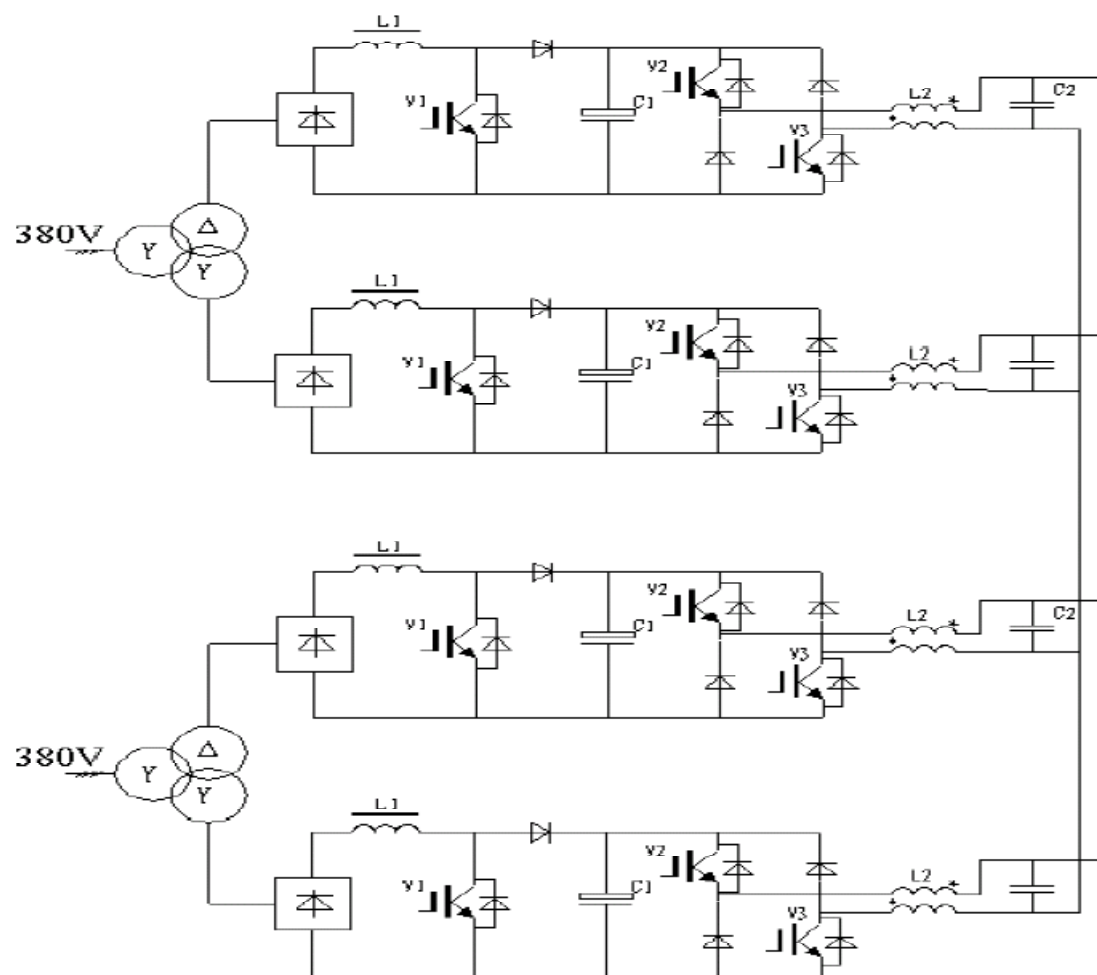


图 1 主电路结构示意图

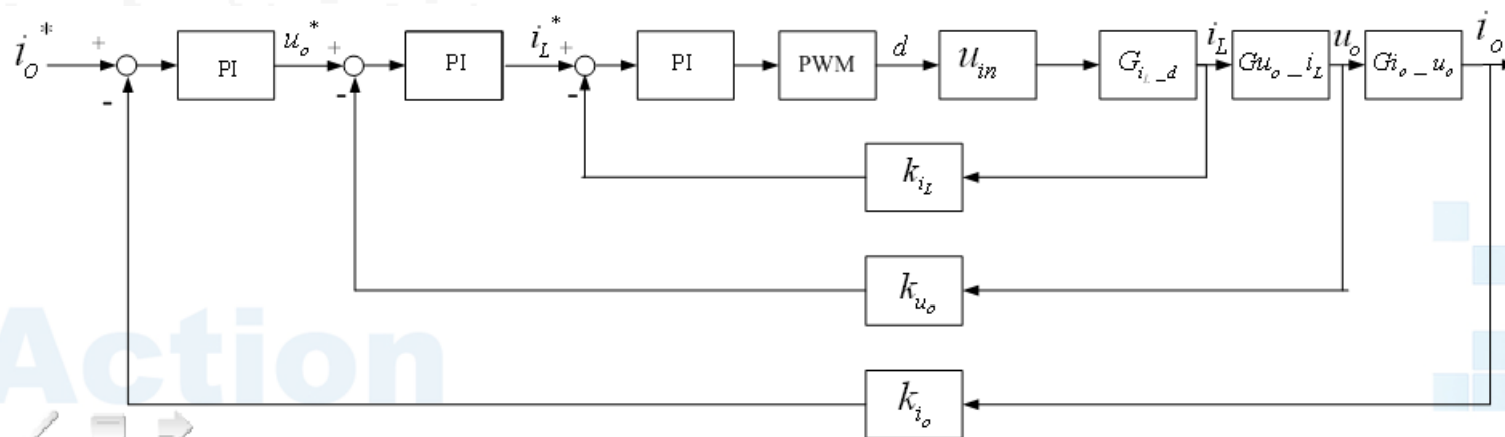
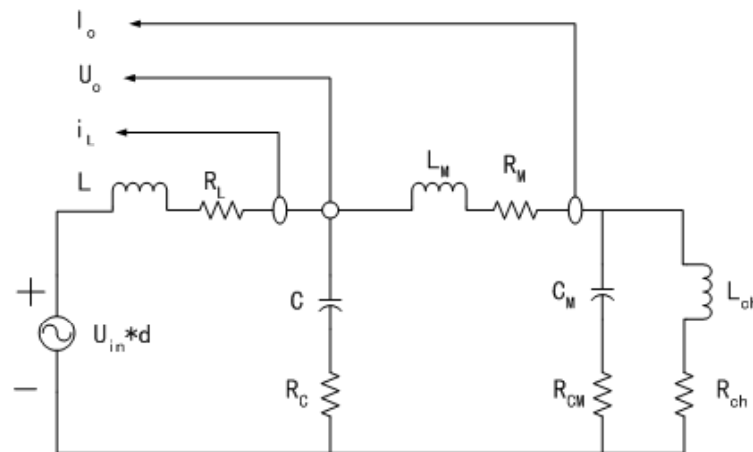


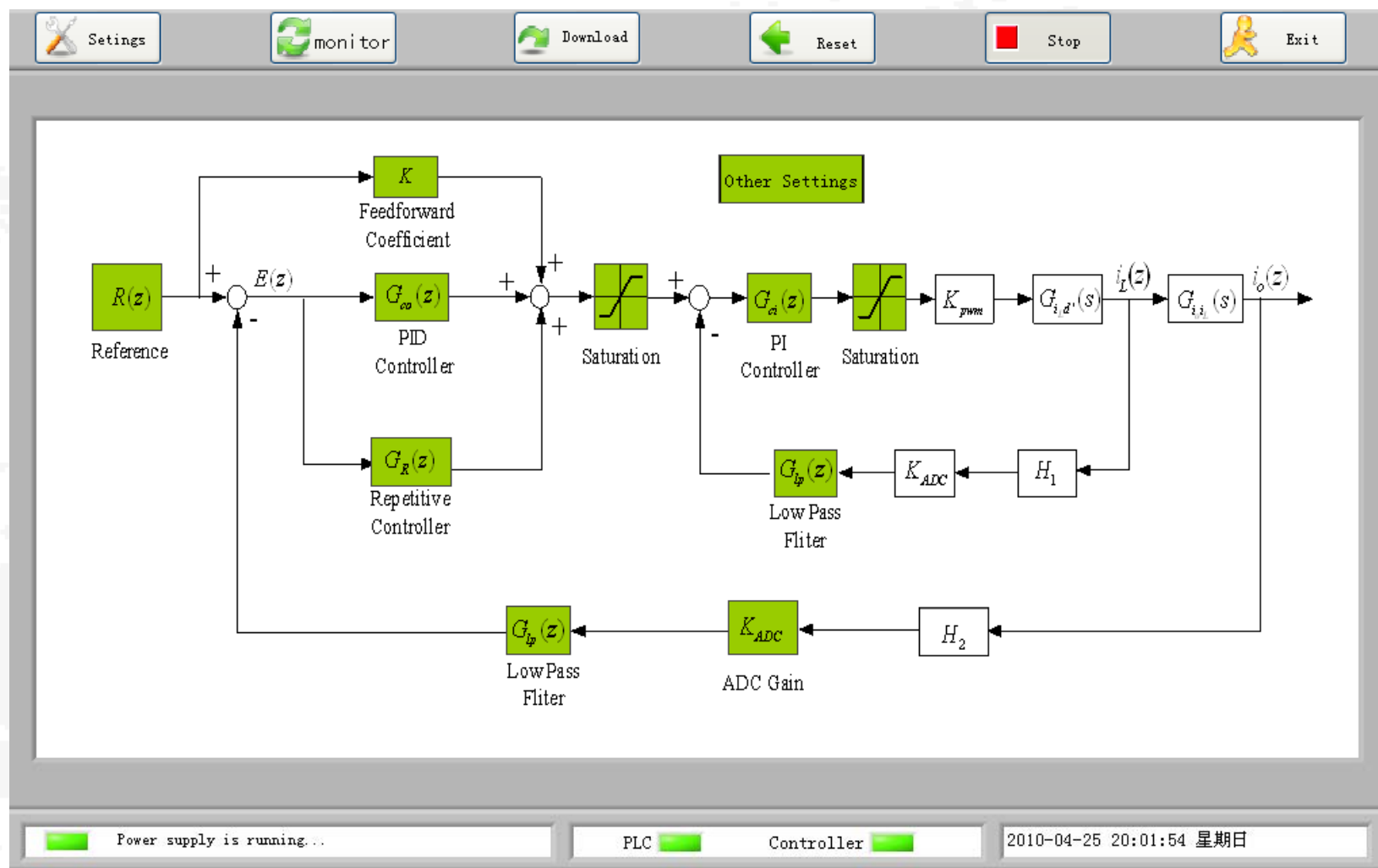


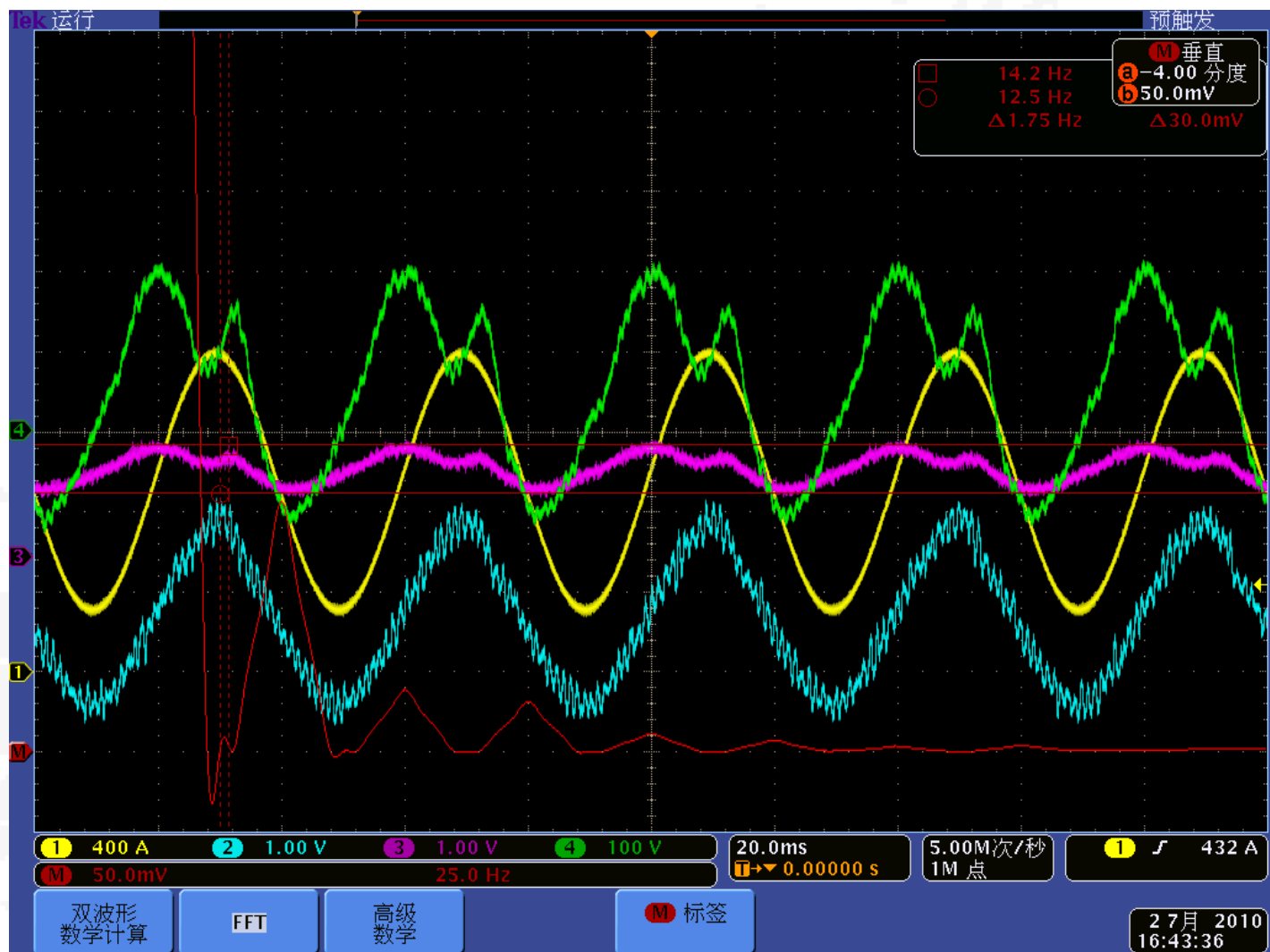
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• Thanks for your attention!

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